



# $\text{Nb}_3\text{Sn}$ for SRF Applications

Ryan Porter  
Cornell University

Supported by:

U.S. DOE award DE-SC0008431: 1.3 GHz coatings + tests

NSF Award 1734189: 2.6 GHz + 3.9 GHz coatings + tests

Center for Bright Beams , NSF Award PHY-1549132: material studies

This work makes use of Cornell Center for Materials Research, NSF MRSEC program (DMR-1719875)





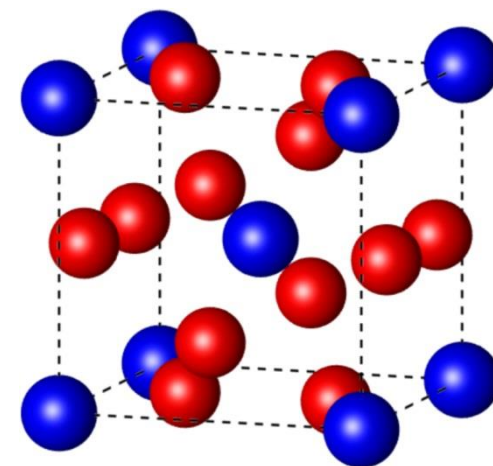
- Introduce  $\text{Nb}_3\text{Sn}$  + standard  $\text{Nb}_3\text{Sn}$  cavity performance
- High frequency  $\text{Nb}_3\text{Sn}$  cavities
- Progress in increasing  $Q$
- Progress in increasing  $E_{\text{acc}}$
- Outlook: gradients, 9-cells
- Conclusion

**Higher critical temperature**

→ Operation at 4.2 K

**Higher superheating field**

→ Double the limit of niobium



Blue: tin

Red: niobium

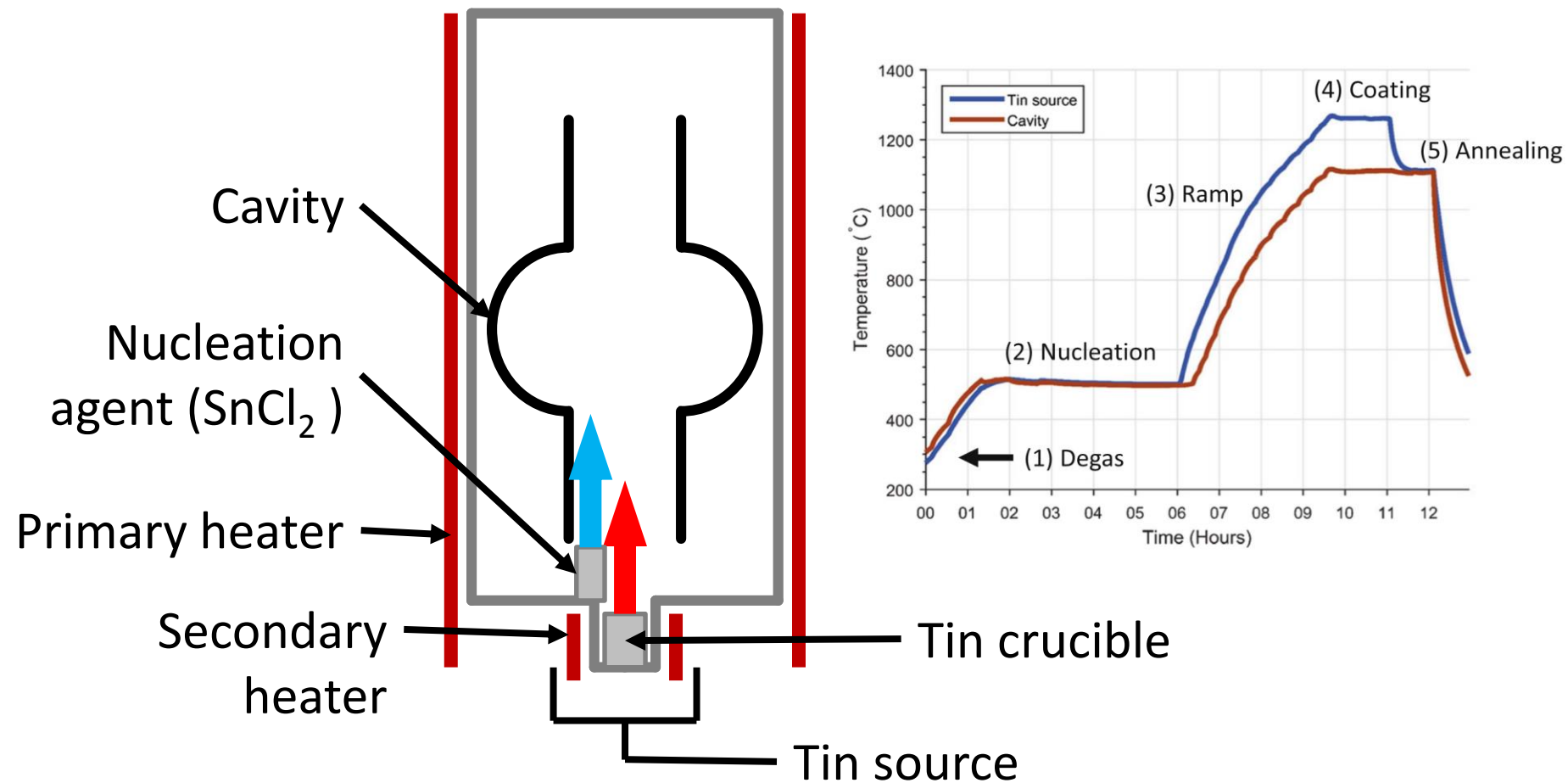
Parameter	Niobium	Nb <sub>3</sub> Sn
Transition temperature	9.2 K	18 K
Superheating field	219 mT	425 mT
Energy gap $\Delta/k_b T_c$	1.8	2.2
$\lambda$ at T = 0 K	50 nm	111 nm
$\xi$ at T = 0 K	22 nm	4.2 nm
GL parameter $\kappa$	2.3	26

**1. Lower losses**

**2. Higher gradients**

**~90 MV/m**

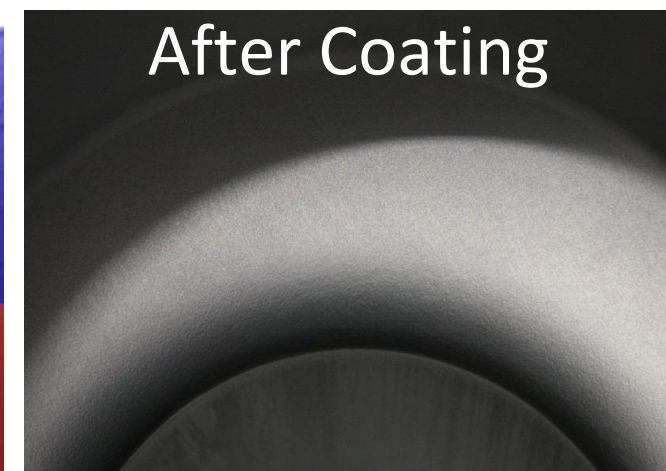
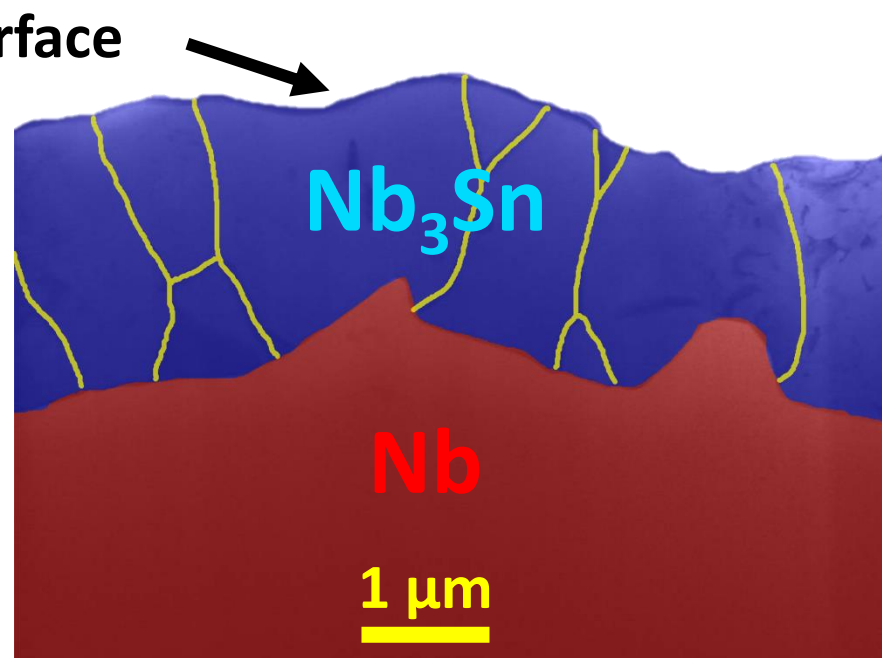
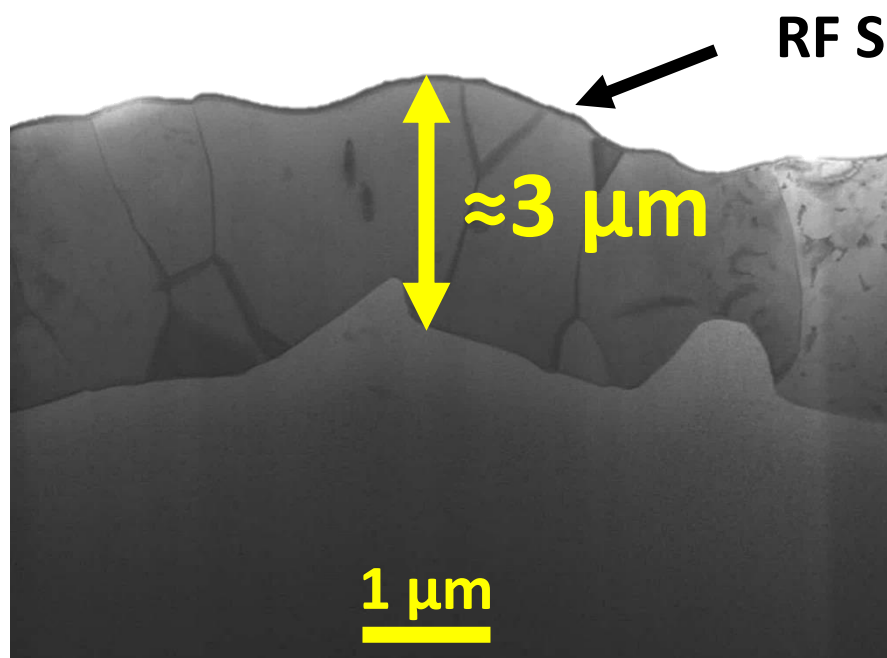
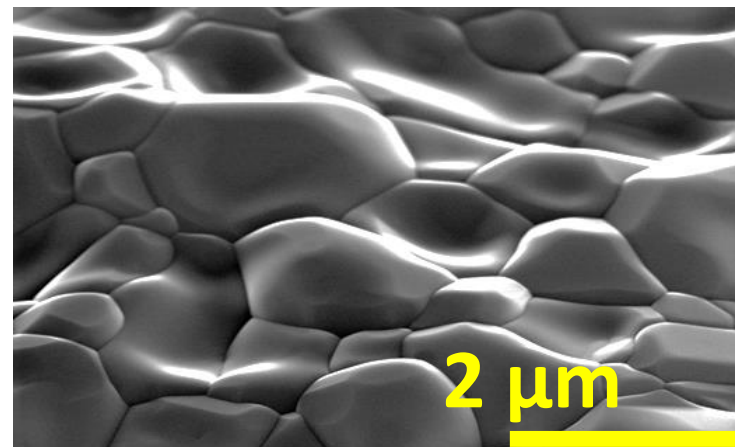
# Cornell Nb<sub>3</sub>Sn Vapor Diffusion Furnace



“Wuppertal” configuration, i.e., with secondary heater for the tin source  
Optimized nucleation and temperature profile

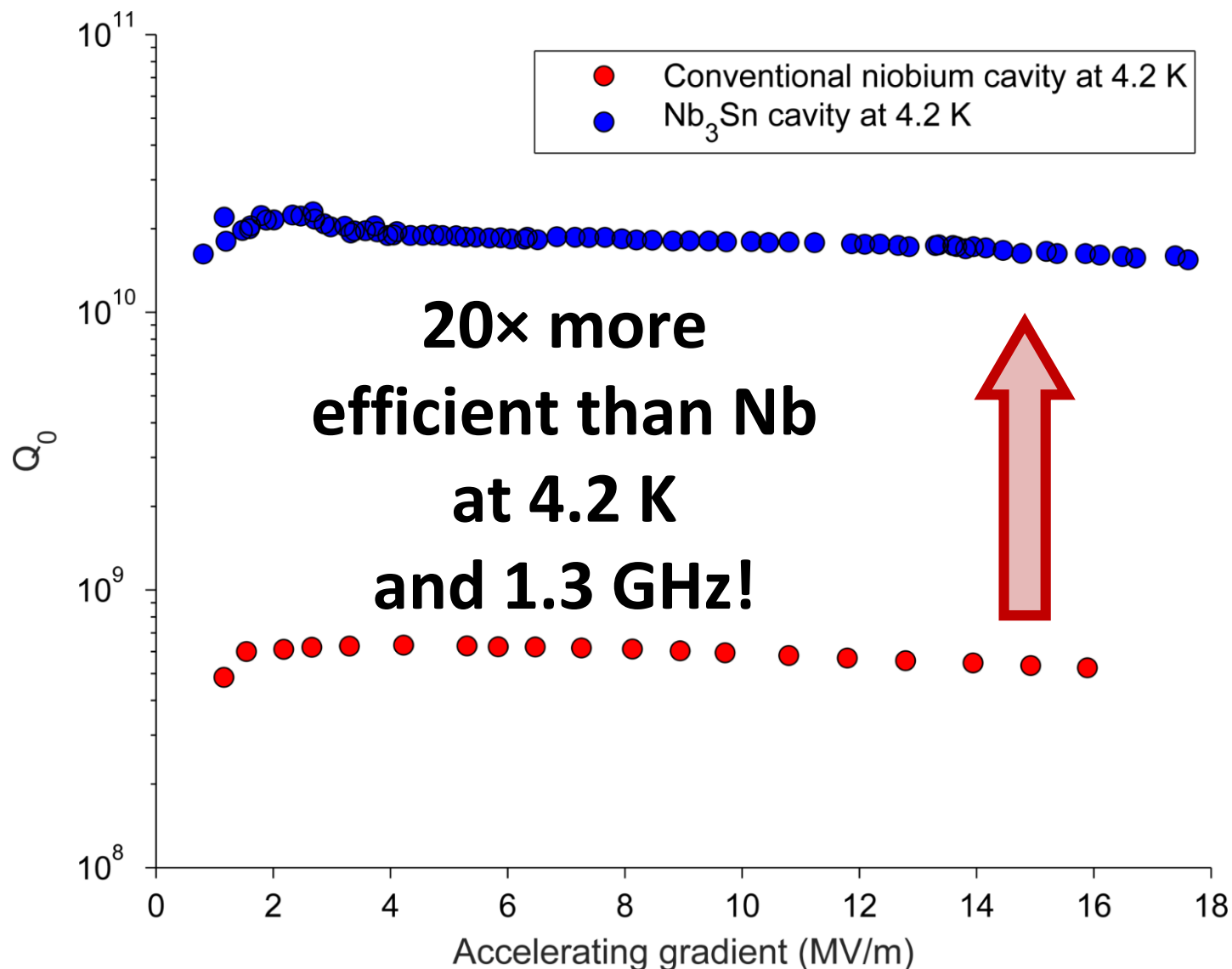
S. Posen and M. Liepe, Phys. Rev. ST Accel. Beams 15, 112001 (2014).

Nb<sub>3</sub>Sn forms a **polycrystalline** layer on the surface of the niobium





# Comparison to Niobium

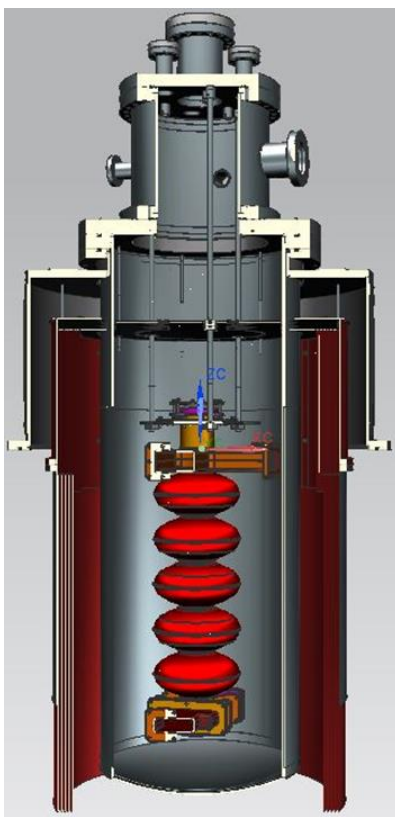


- High Q at 4.2 K
  - More efficient
    - Lower dynamic load
  - Longer pulsed operation
- Could run at 4.2 K
  - Simplify cryomodule
    - Lower static load
  - Simplify cryogenic system



## JLAB Nb<sub>3</sub>Sn Coating System

Jefferson Lab



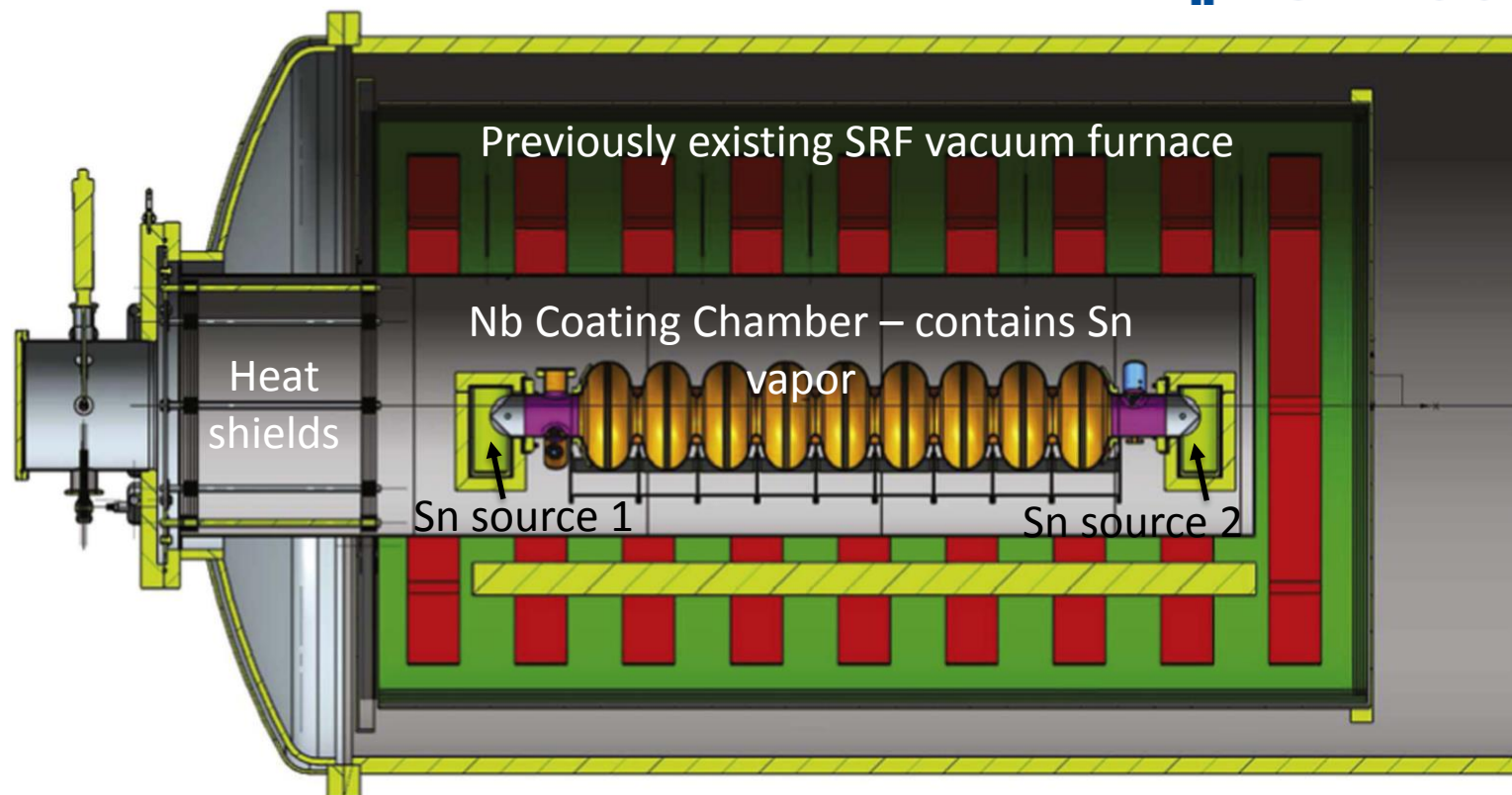
“Siemens” configuration, i.e., no  
secondary heater for the tin source

31/10/2019

## Fermilab Nb<sub>3</sub>Sn Coating System

Sam Posen

Fermilab



“Wuppertal” configuration, i.e., with  
secondary heater for the tin source

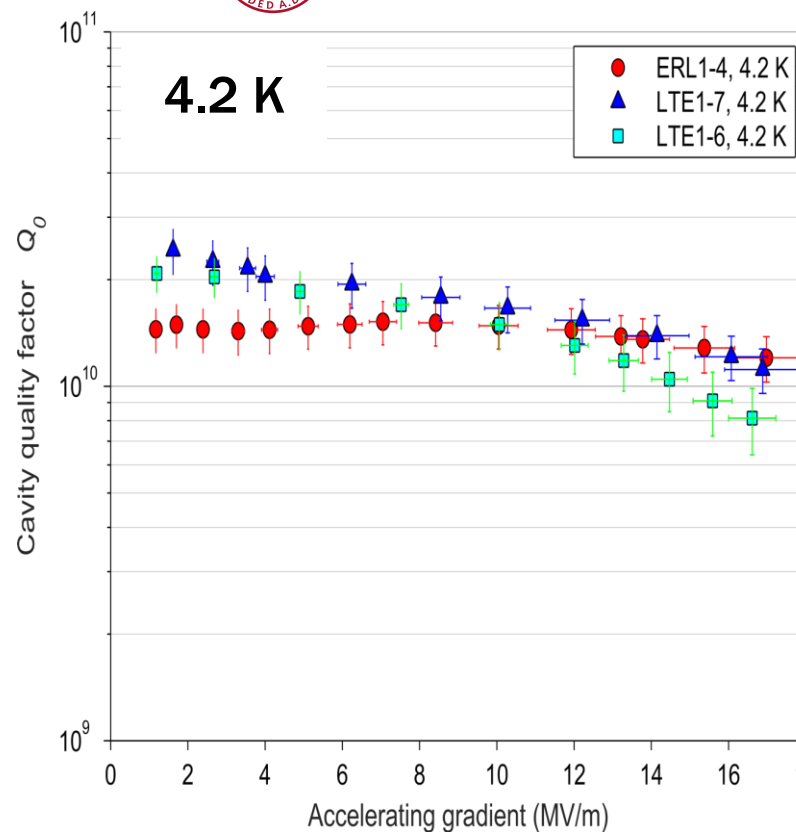
Ryan Porter LCWS 2019



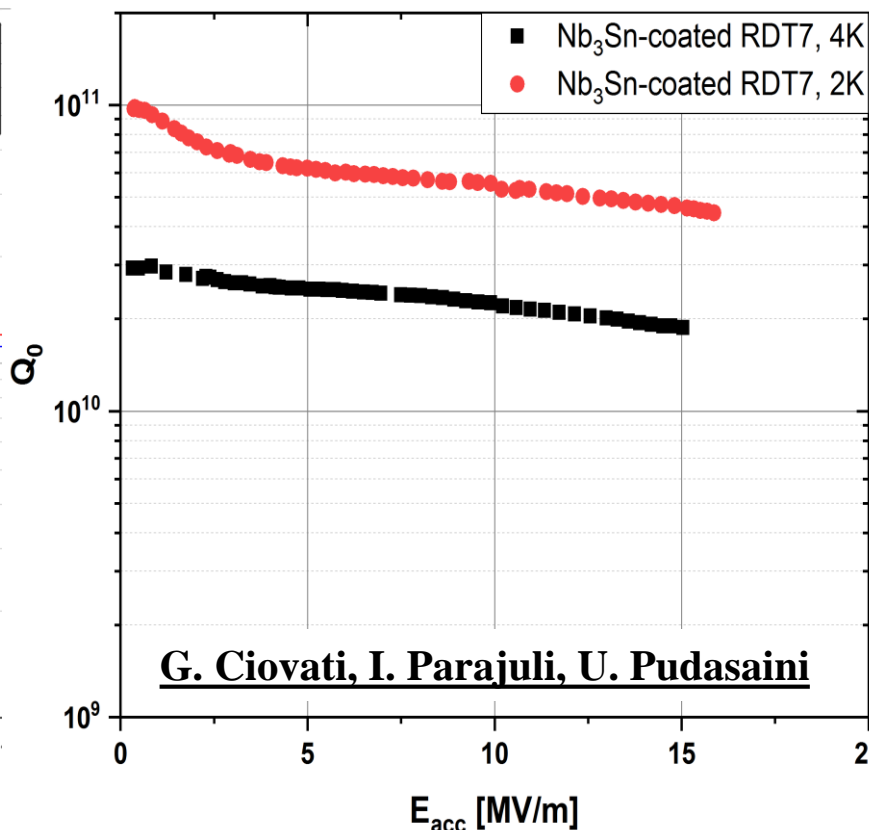
# 1.3 GHz Nb<sub>3</sub>Sn Cavity Performance: JLab and Fermilab



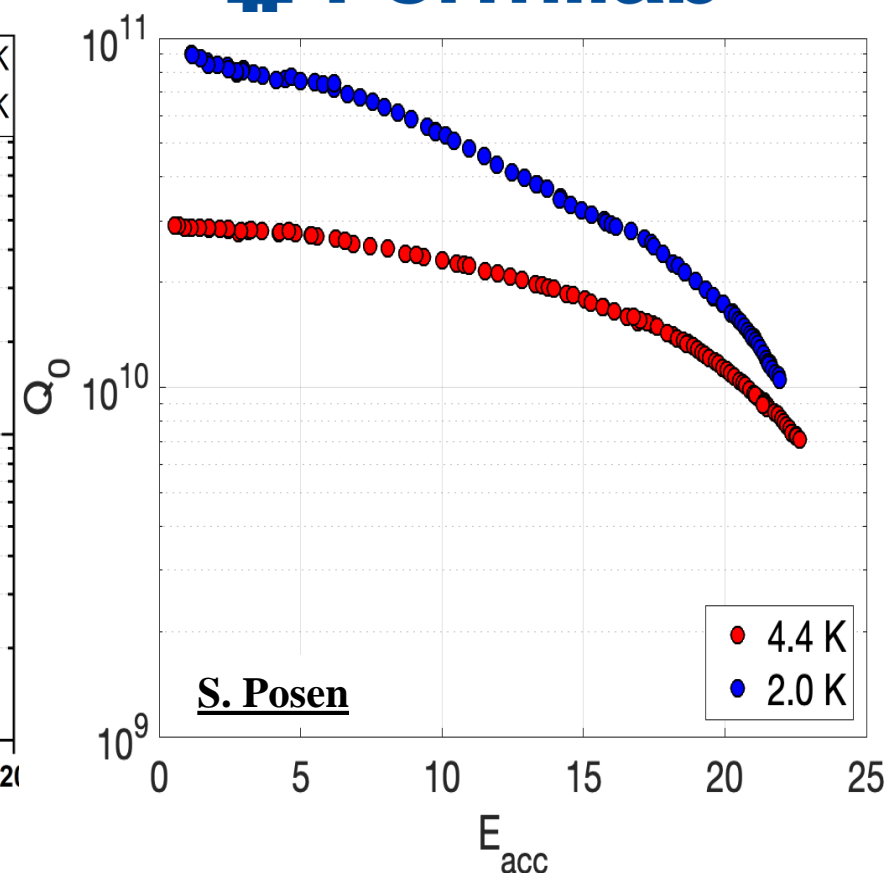
Cornell University



Jefferson Lab



Fermilab

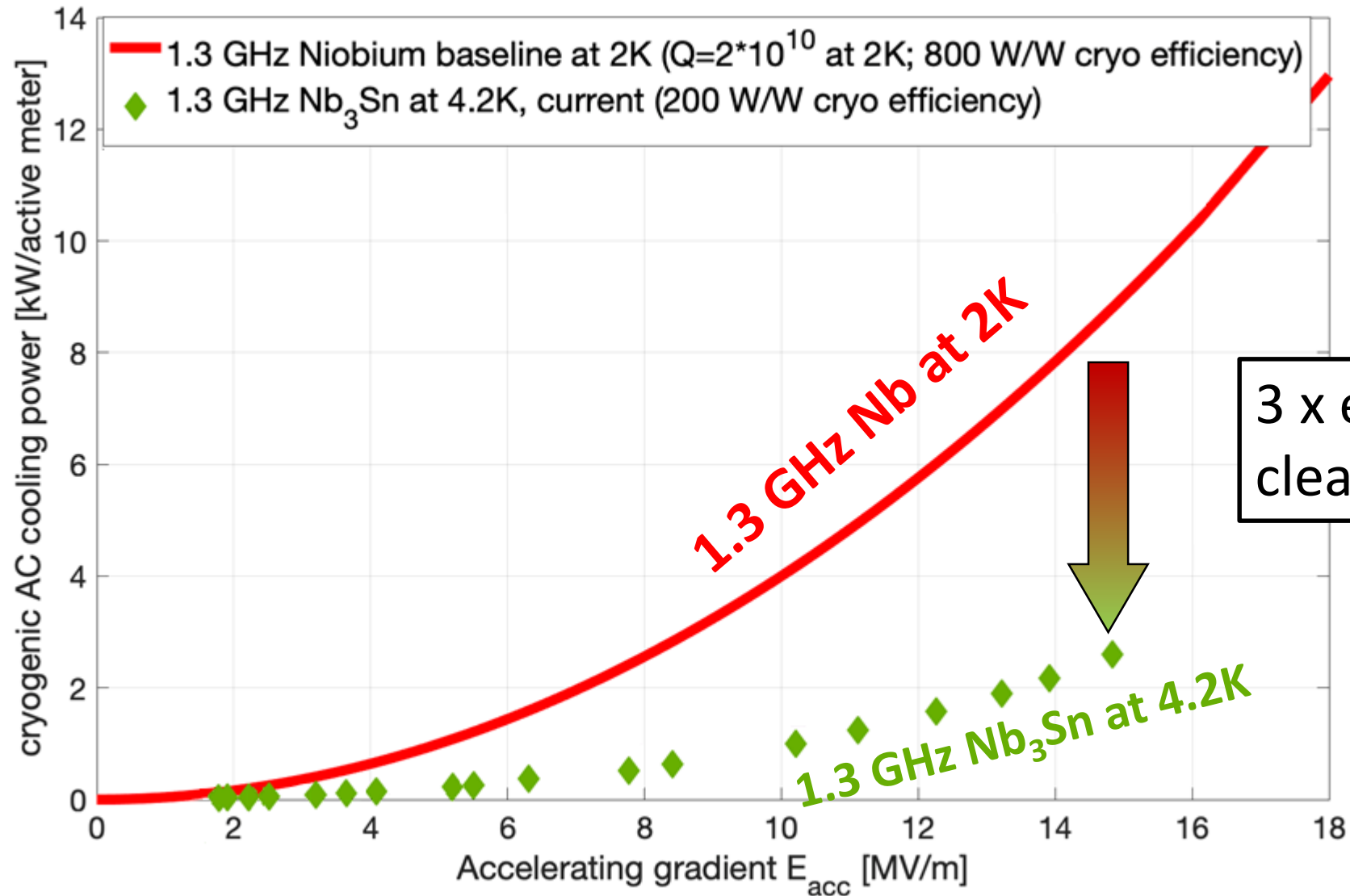


- Very reproducible performance
- ~4K operation with unprecedented  $Q > 10^{10}$  at typical CW operating fields



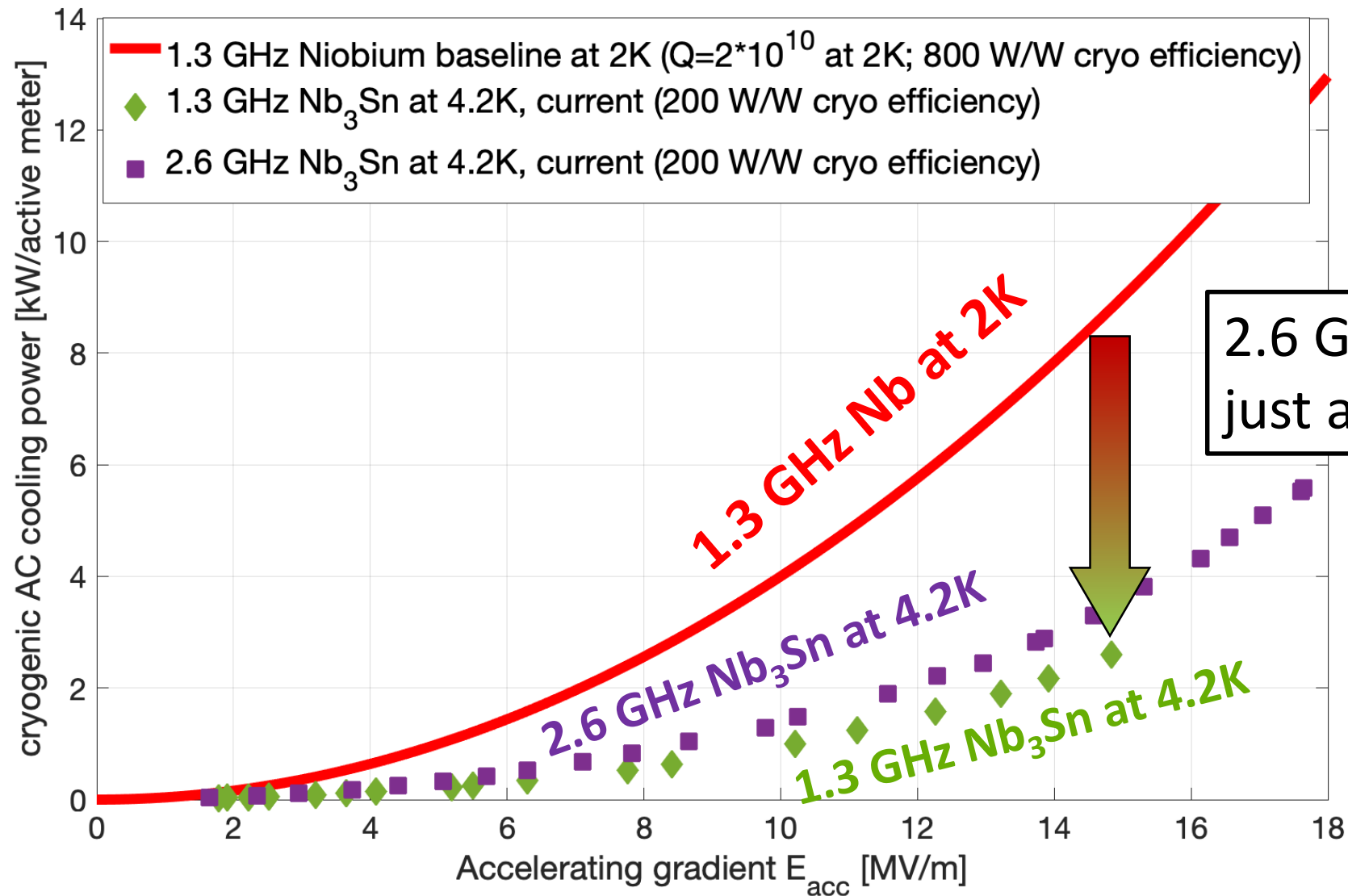


# Cryo-Efficiency





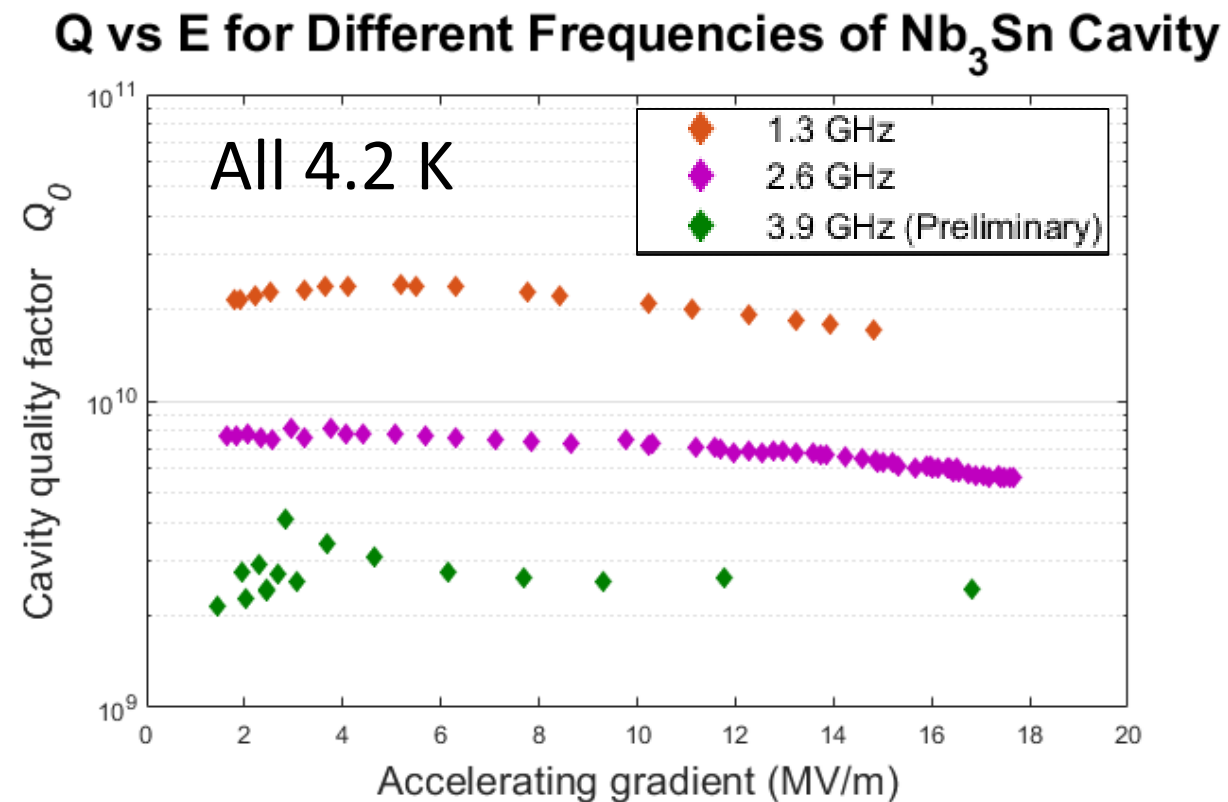
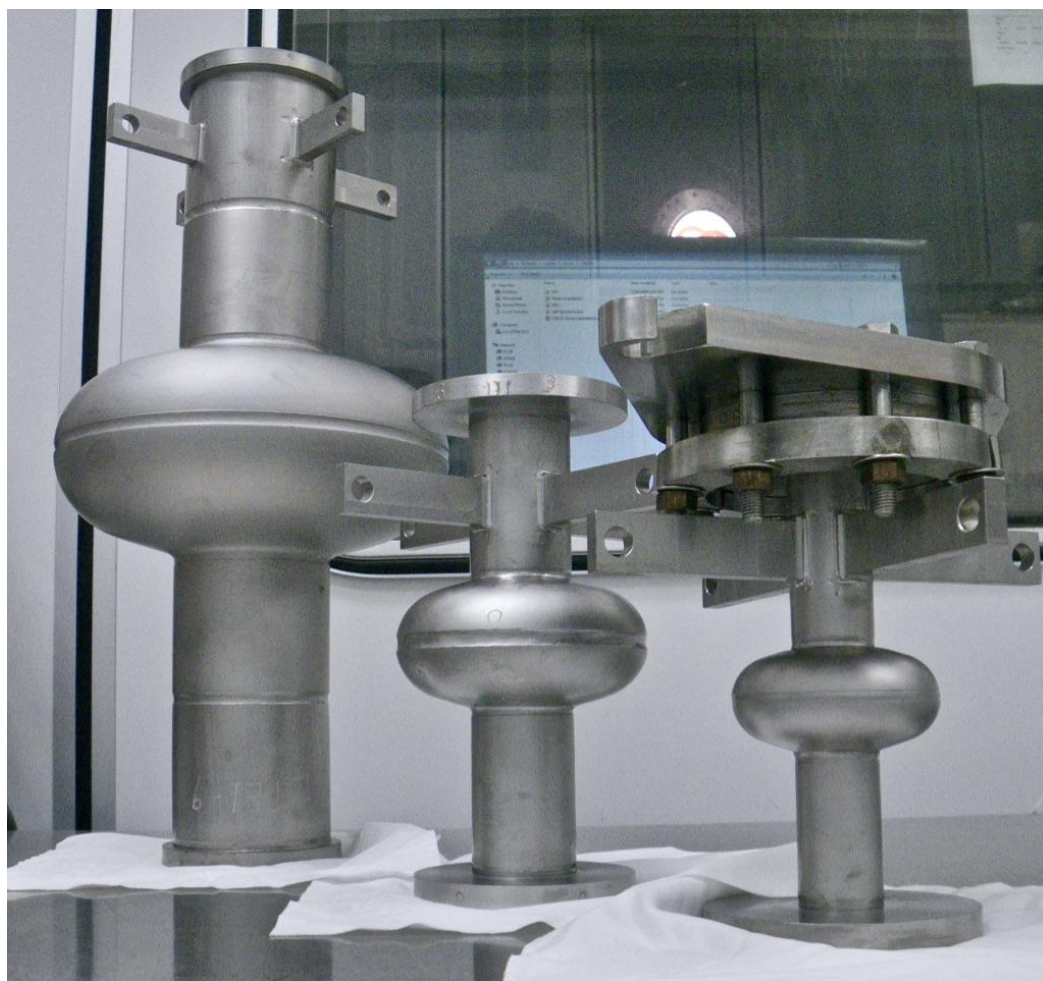
# Cryo-Efficiency





# High Frequency Nb<sub>3</sub>Sn Cavities

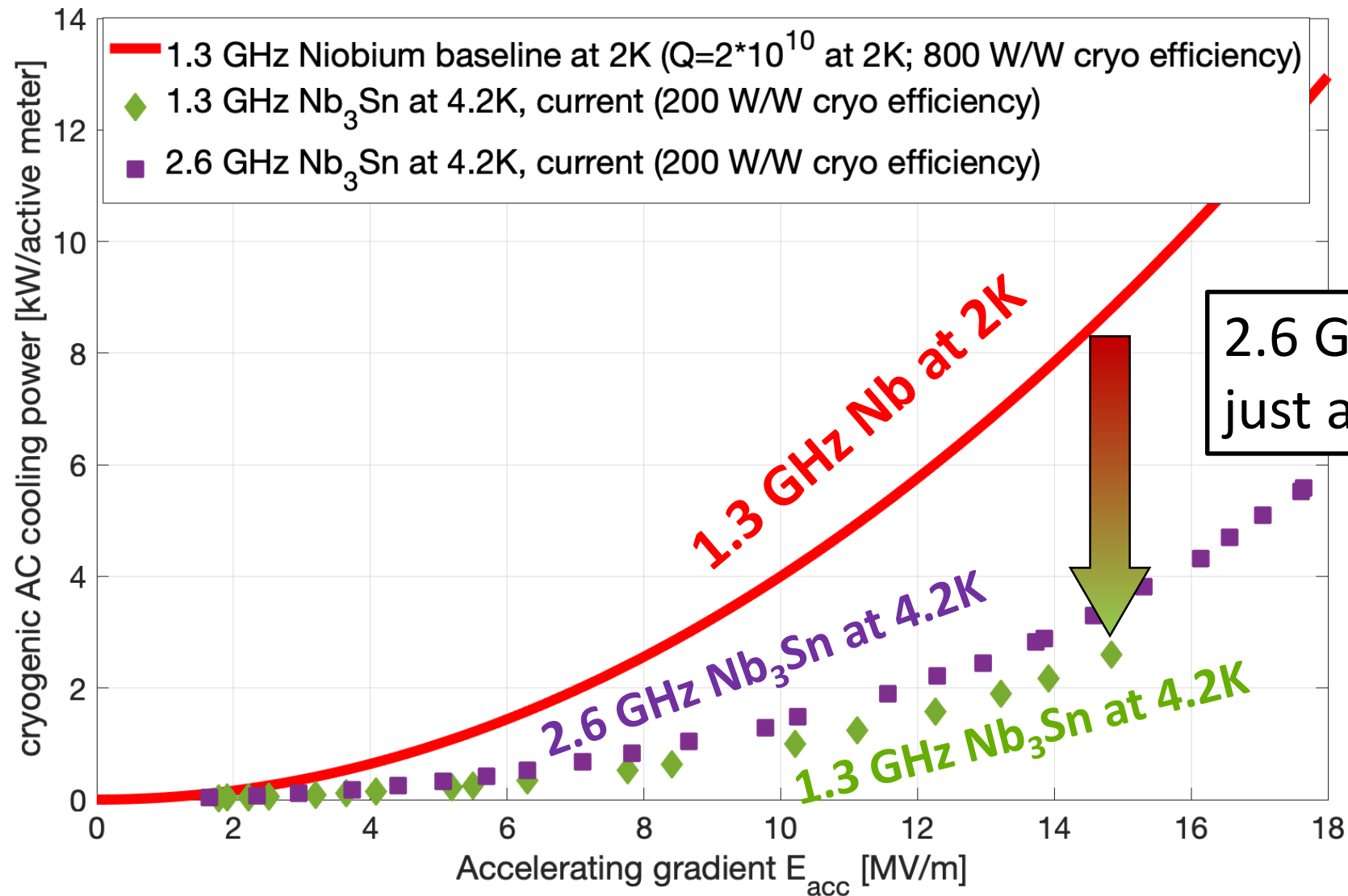
# High Frequency Nb<sub>3</sub>Sn



**Higher frequency -> Smaller cavities-> Material savings**



# Cryo-Efficiency





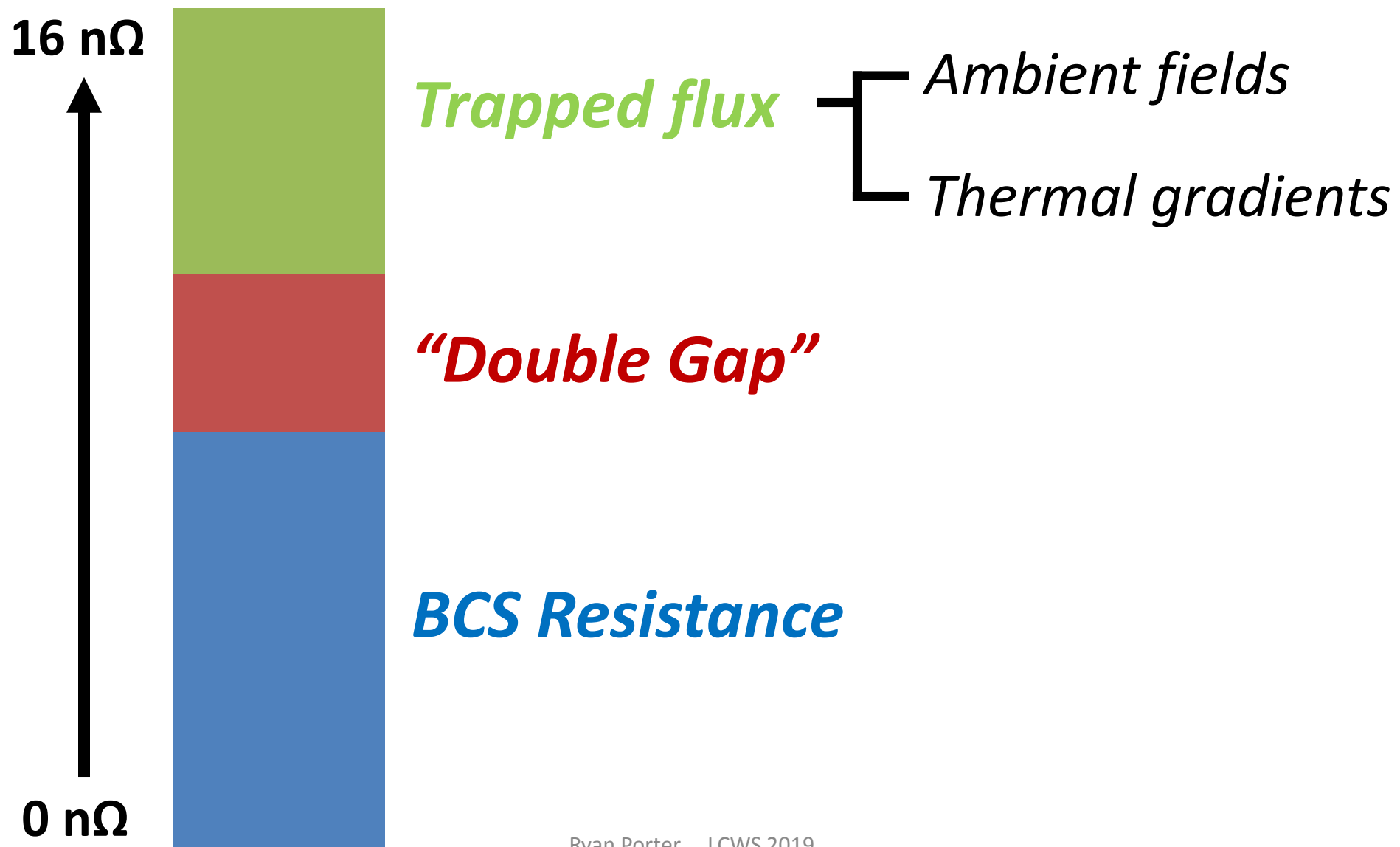


# Increasing $Q$ ?



# Breaking down the $Q$

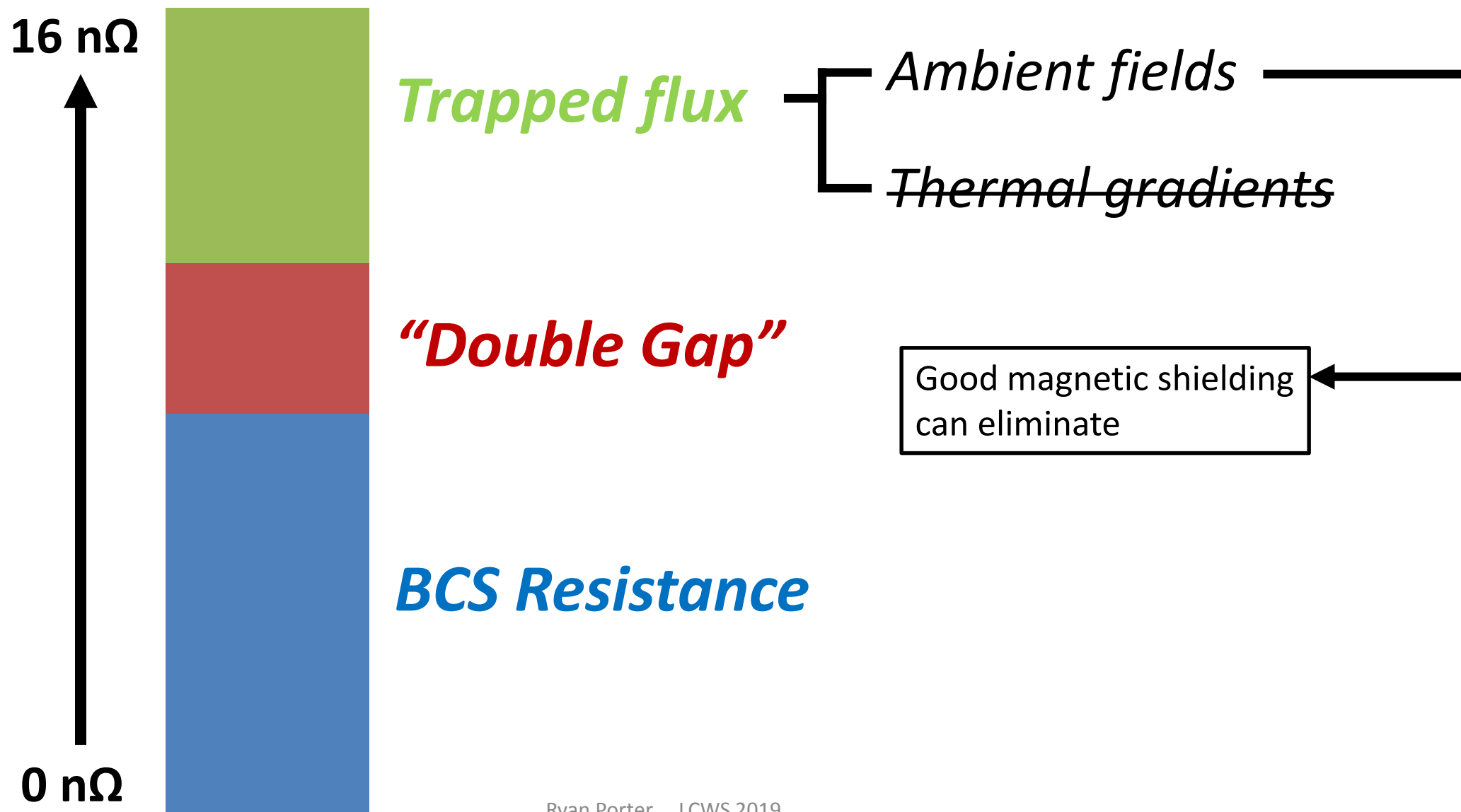
Surface resistance at 4.2 K and 10 MV/m





# Breaking down the $Q$

Surface resistance at 4.2 K and 10 MV/m





# “Double Gap”

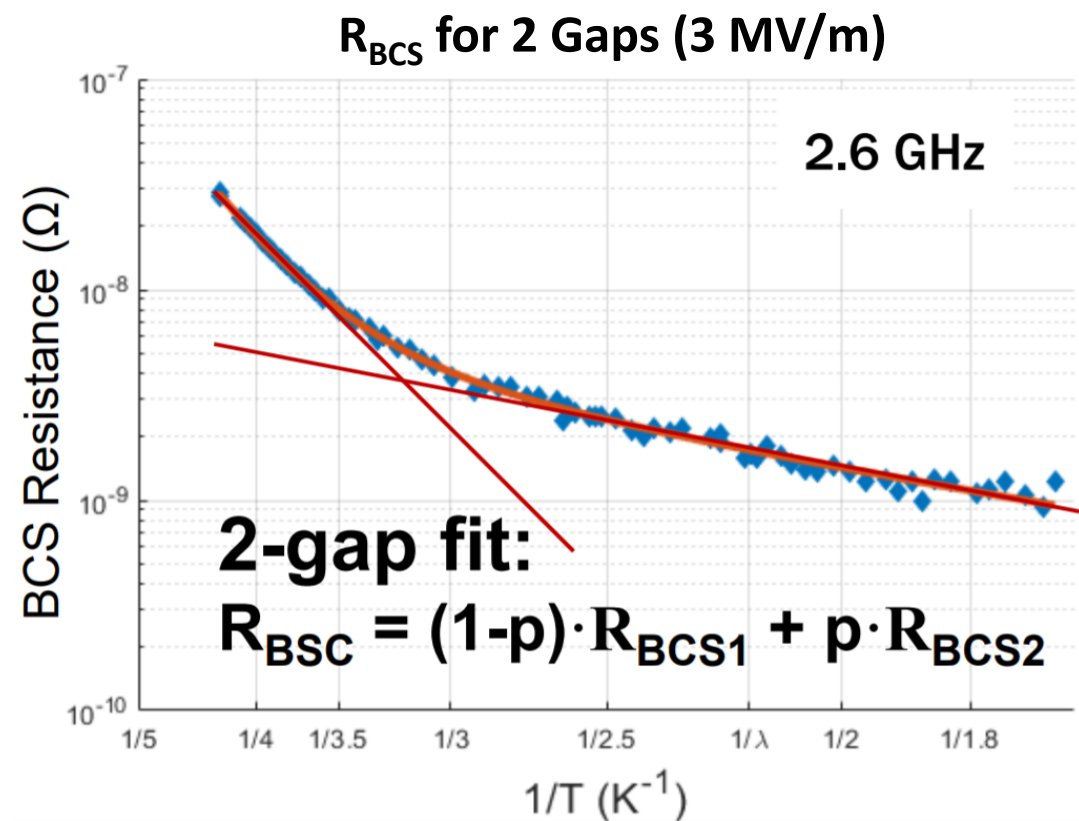
- “BCS” resistance shows two slope behavior
- Cause still under investigation:

- Well fit for “2-gap” BCS
  - Multiple regions of “Sn depleted”  $\text{Nb}_3\text{Sn}$ ?
- Dirty surface layers?

- **Good news:**

- Removing will increase Q:

- $Q_{2.6 \text{ GHz}, 4.2 \text{ K}} \rightarrow 9 \cdot 10^9$
- $Q_{1.3 \text{ GHz}, 4.2 \text{ K}} \rightarrow 2.3 \cdot 10^{10}$   
 $\rightarrow 3.5 \cdot 10^{10}$  with good magnetic shielding



$R_0 \sim 5.5 \text{ n}\Omega$  (from trapped magnetic flux)



# Increasing $E_{\text{acc}}$

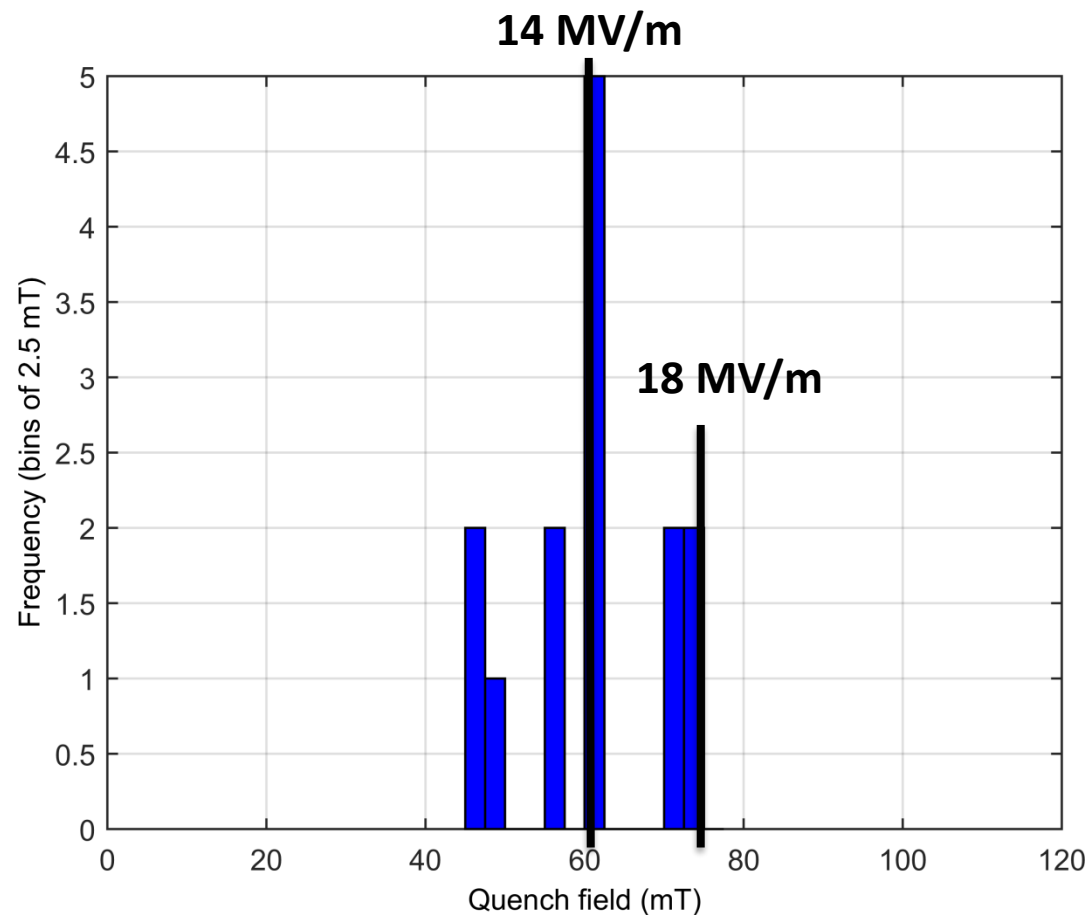




# Limitations in quench field

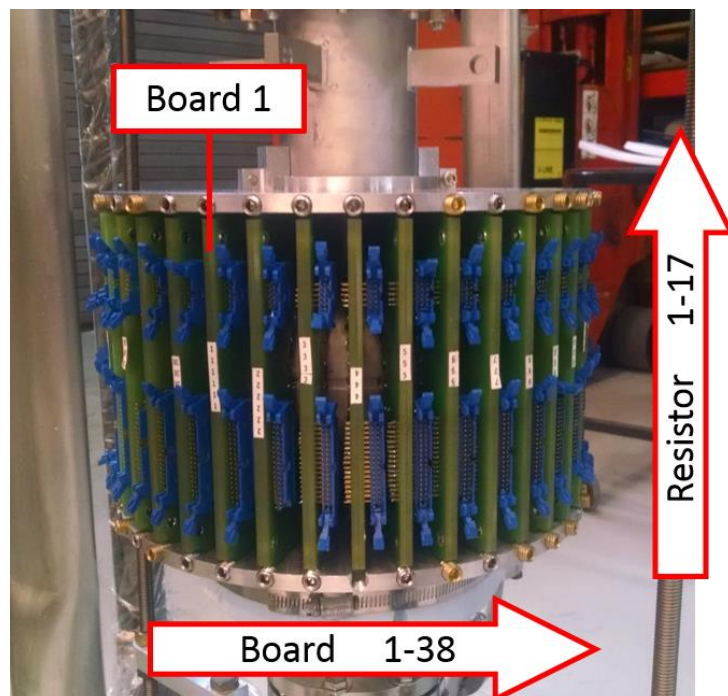
Nb<sub>3</sub>Sn cavities consistently quench at fields between  
**14 and 18 MV/m in CW operation**

The superheating  
field suggests we  
can achieve fields  
up to **96 MV/m!**

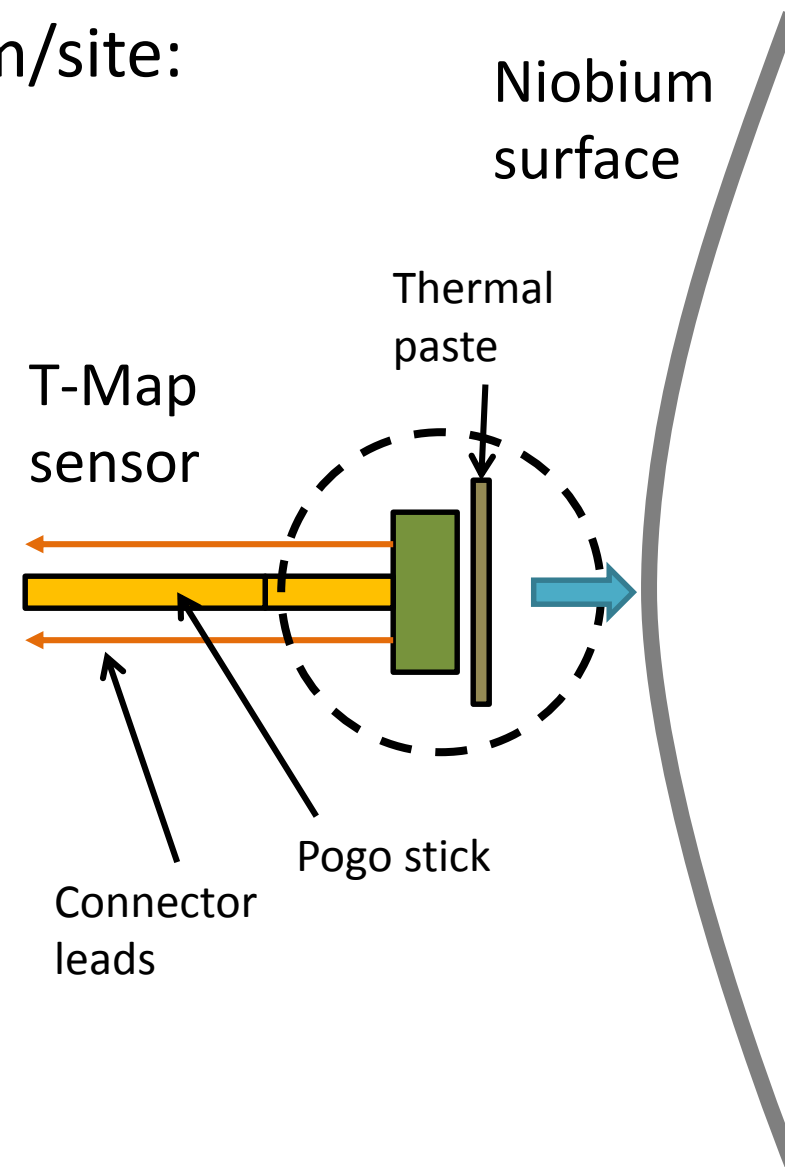
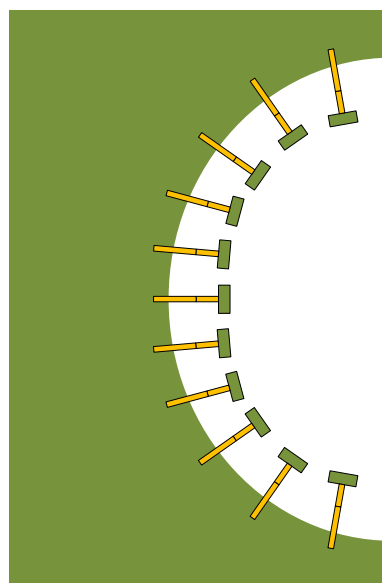


# T-Map experiment

Use temperature map to look for quench mechanism/site:

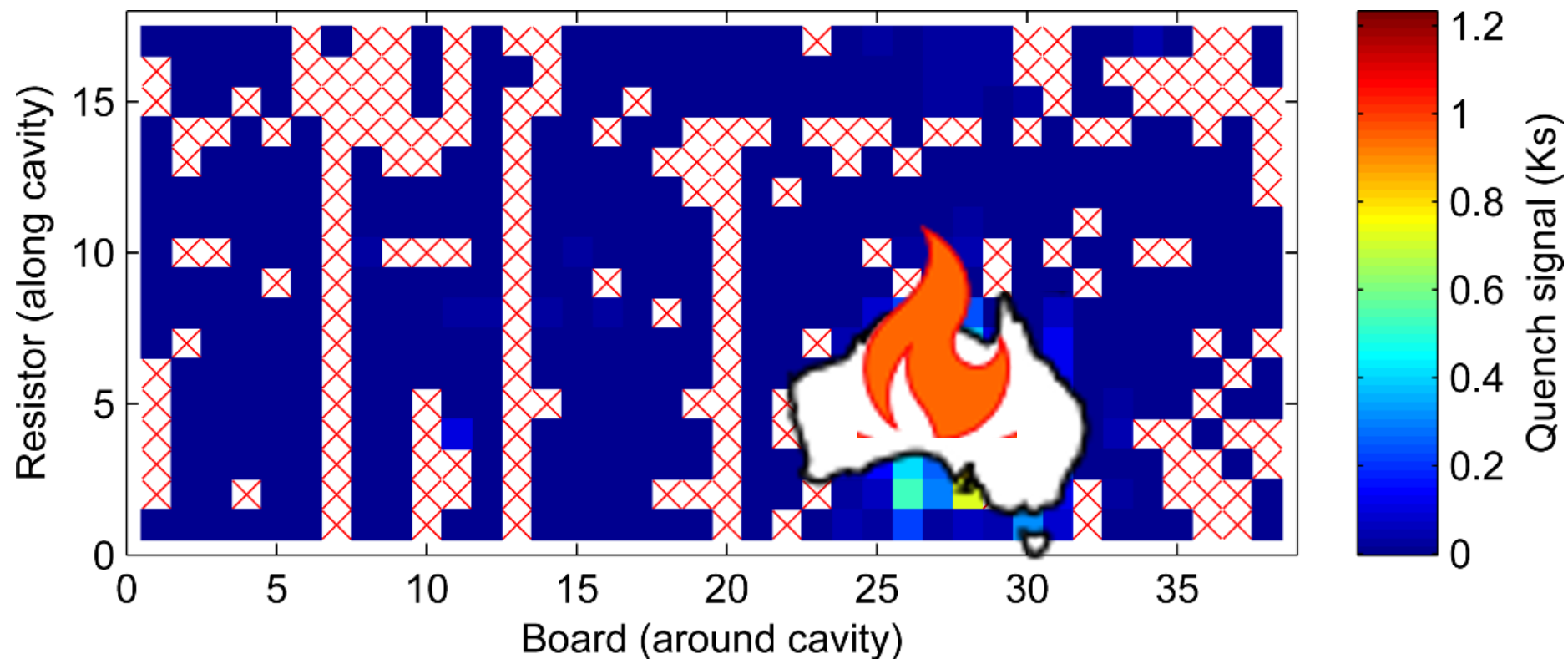


T-Map board





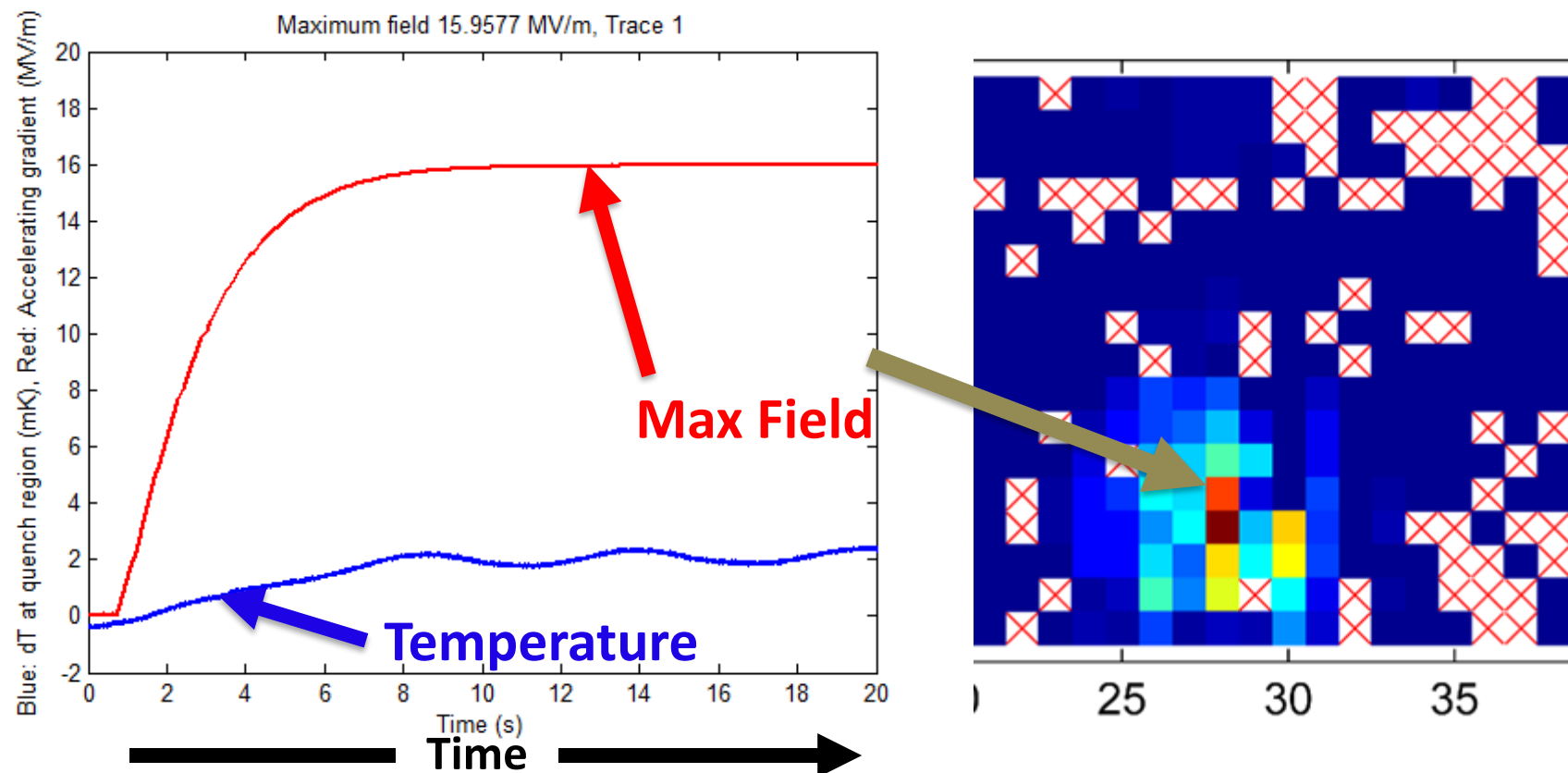
$\text{Nb}_3\text{Sn}$  cavities are limited by a quench at a localized spot



What could be at fault?

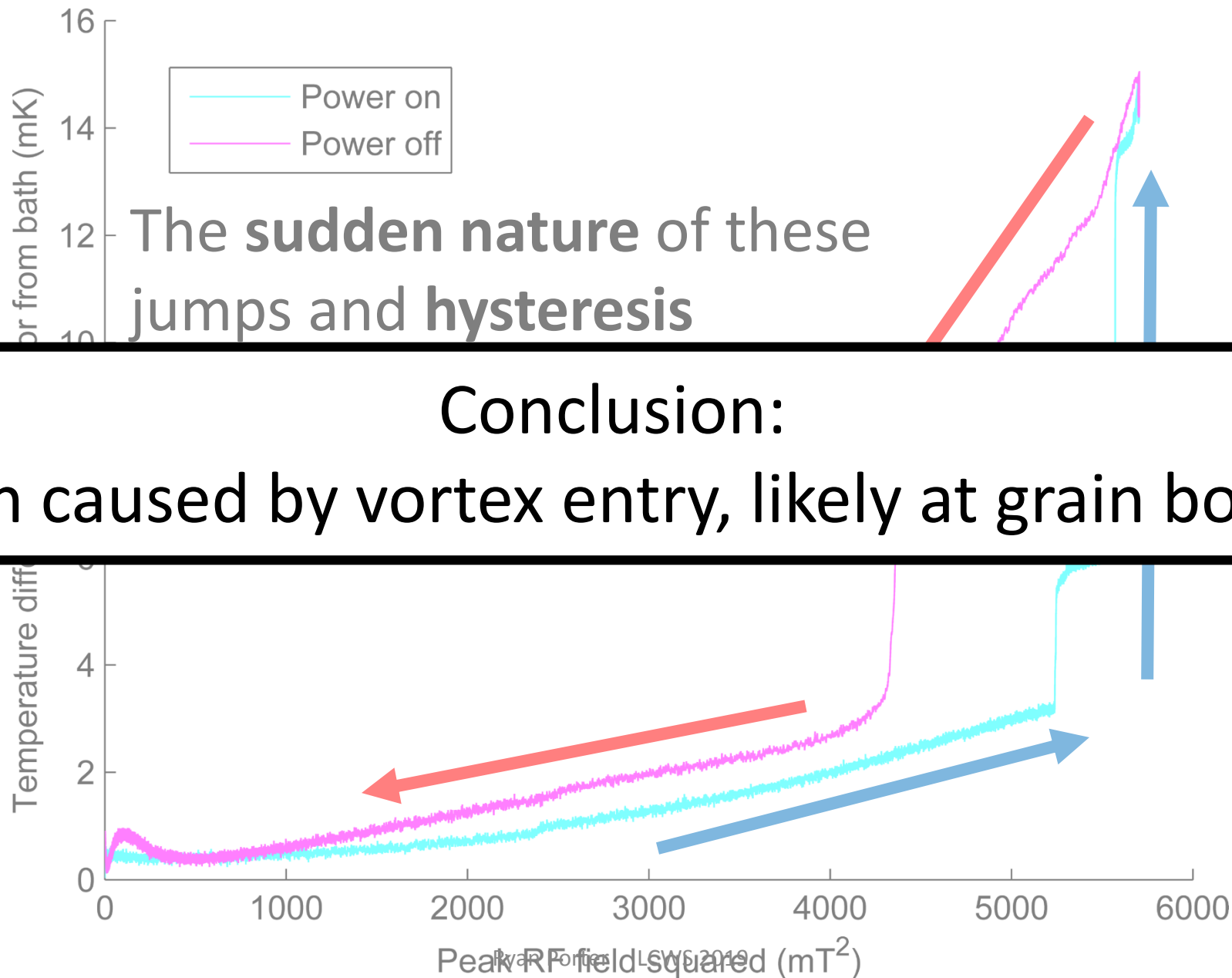
# Near quench behavior

- Measure temperature of sensor near the quench point as field is increased



- Sudden jumps in temperature

# Near quench behaviour



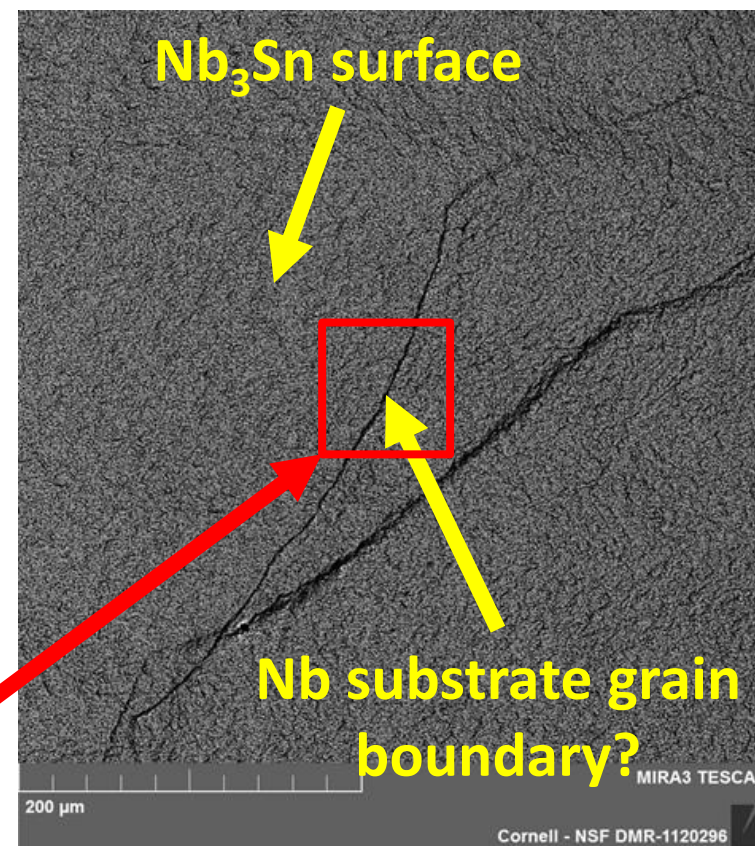


# Cavity Autopsy – Anything on Surface?

- Cut out this region and examined with microscopy
- Nothing obvious except Nb grain boundary cliff  
– Rough Surface

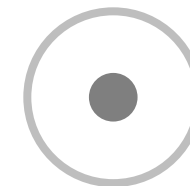


Quench Site



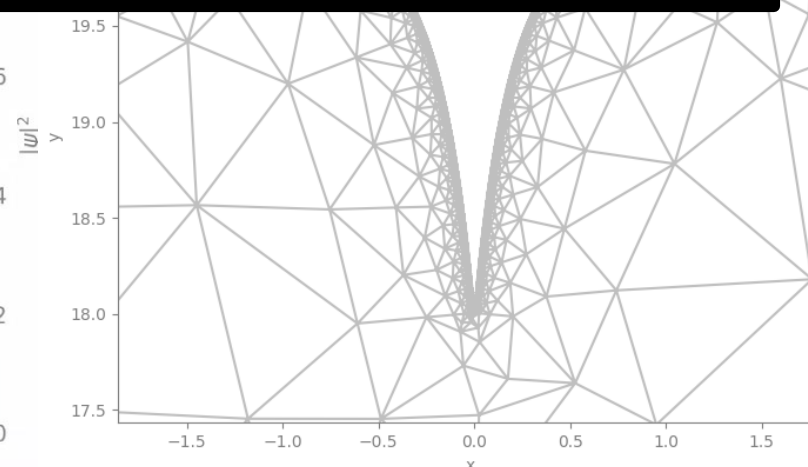
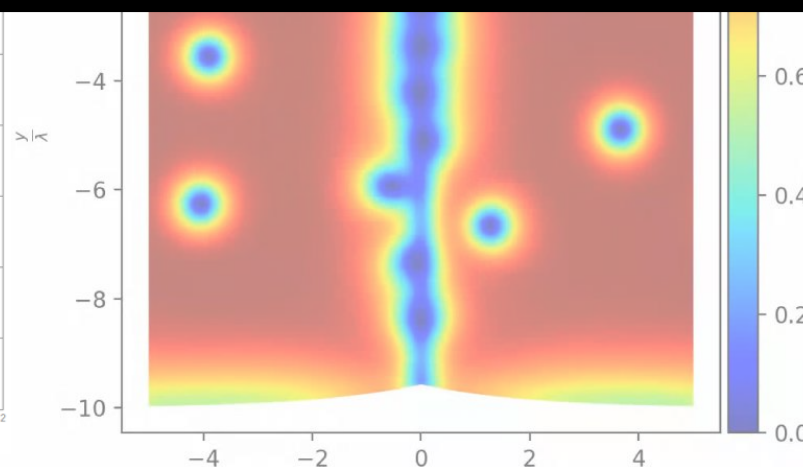
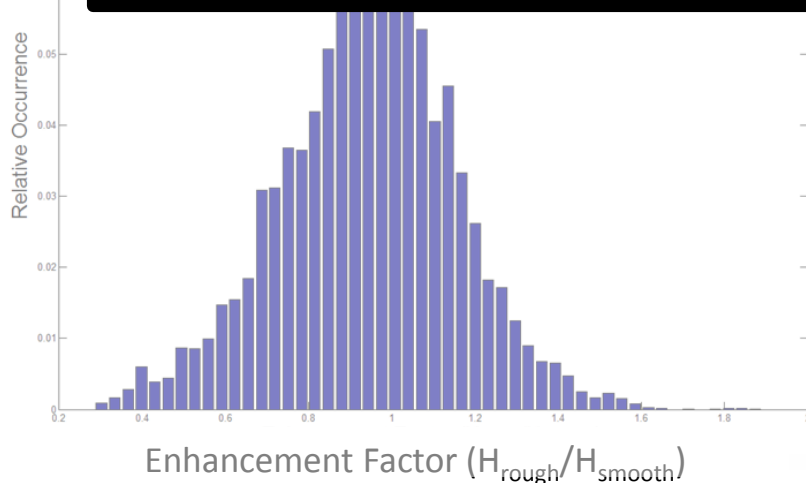
## Surface Roughness:

- Rough surface → increased magnetic field on some surfaces
  - Quench field decreased by 1/3 (?)
- Poor grain boundary geometry can decrease magnetic flux entry barrier
  - A. R. Pack, M. Transtrum (BYU): SRF'19: MOP017



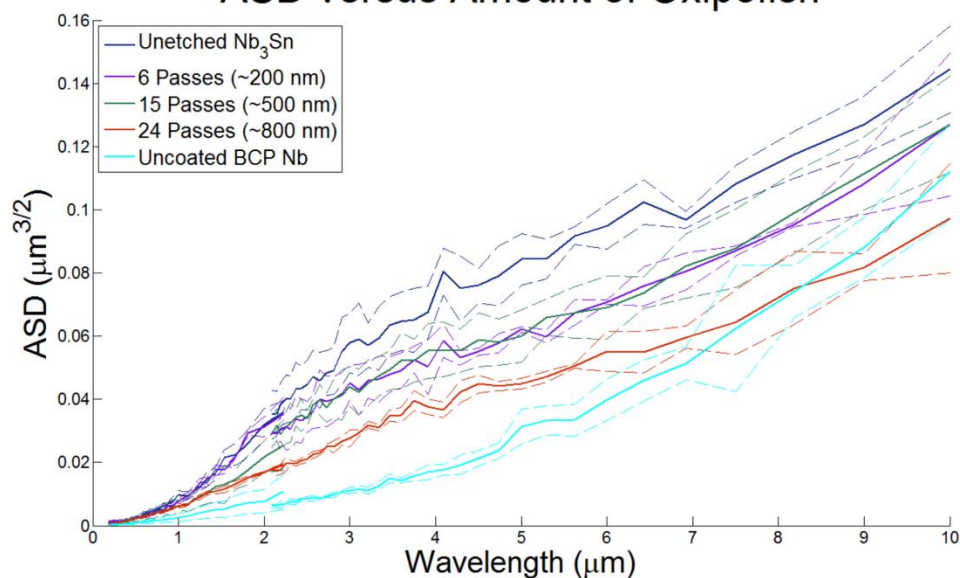
## Conclusion:

Grain boundary geometry/roughness lowers quench field

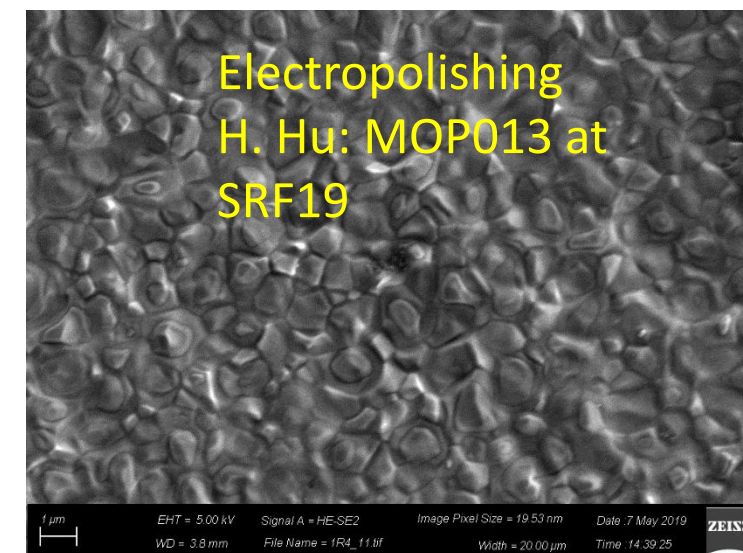
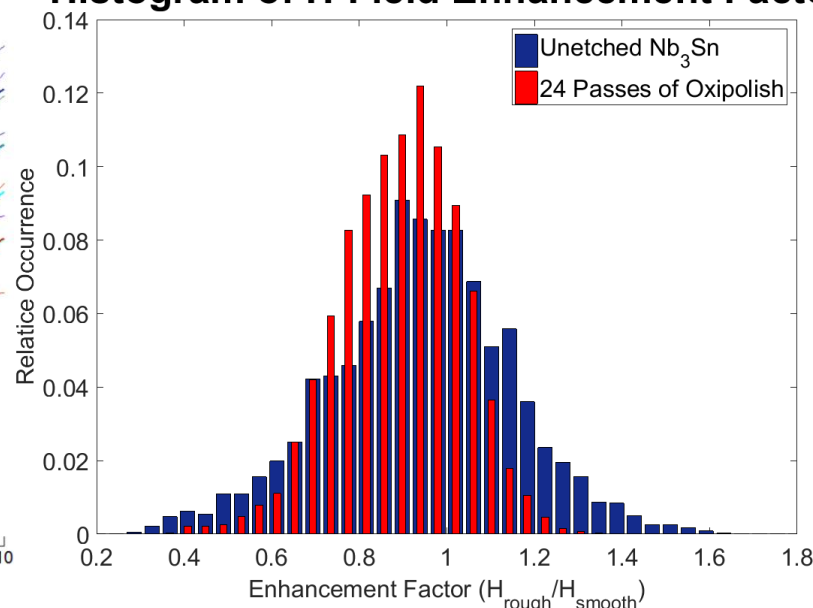


- Developing surface treatments to reduce surface roughness
- Early result: Oxypolishing **halves roughness and surface field enhancement** with 800 nm removal

ASD versus Amount of Oxipolish



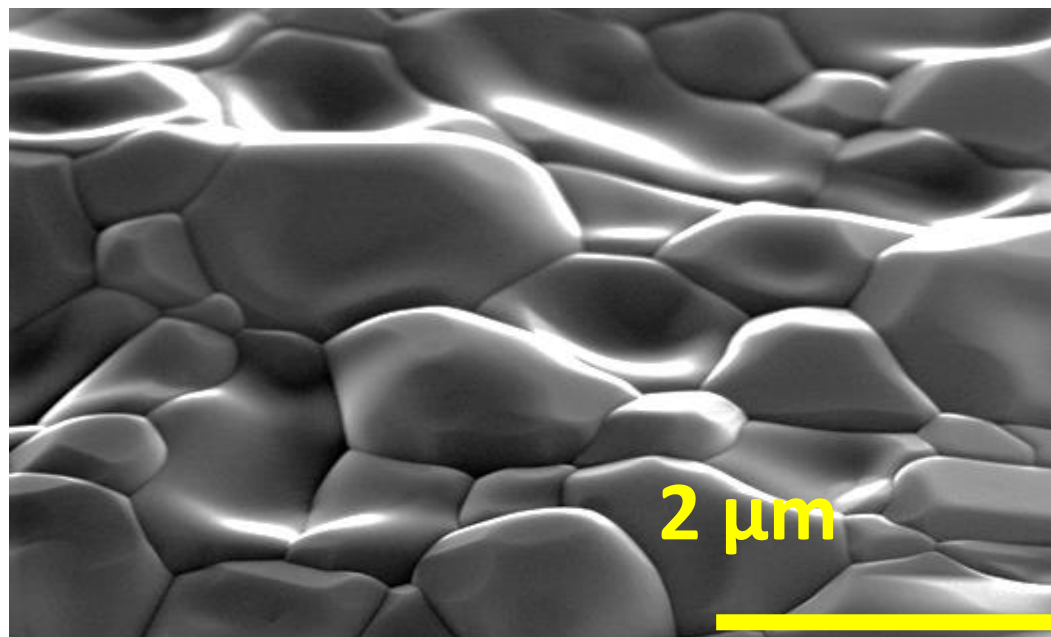
Histogram of H-Field Enhancement Factor



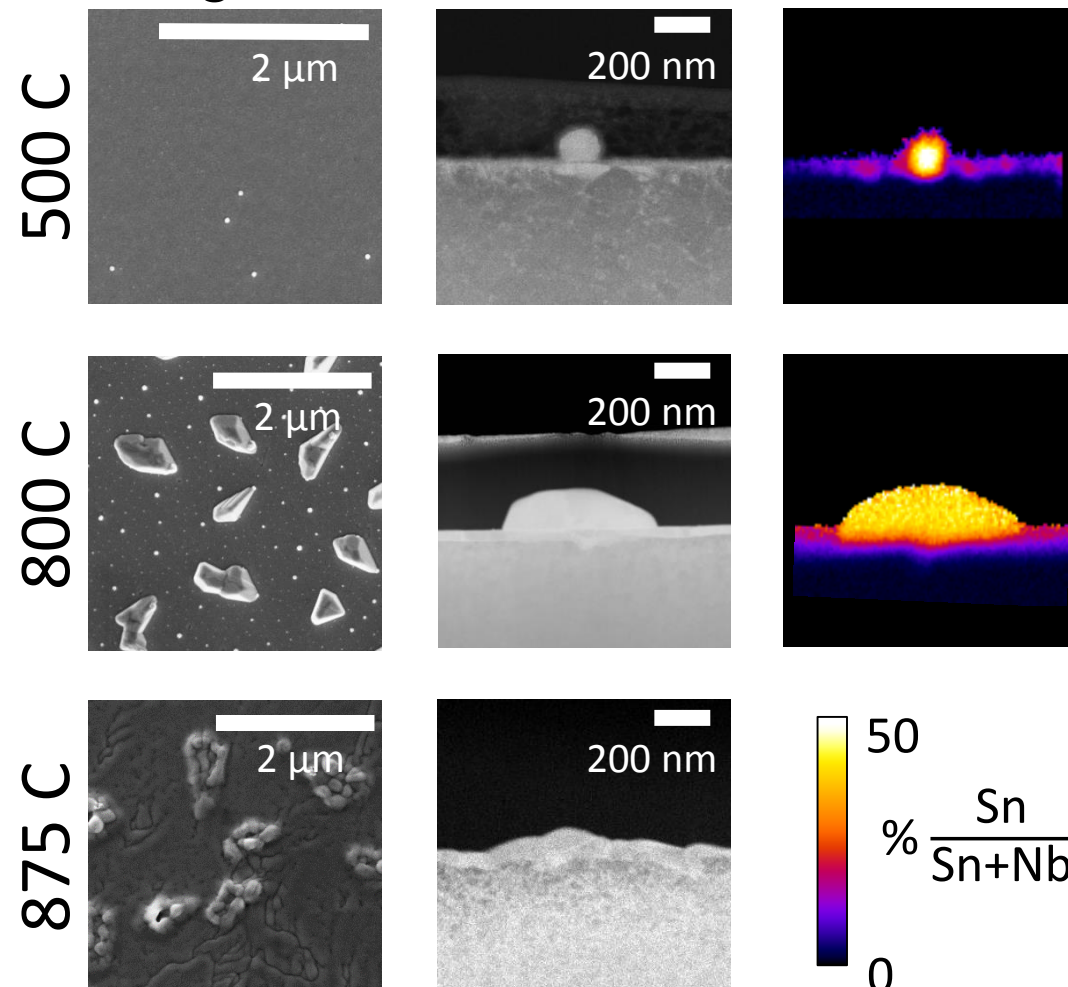


# Why is Nb<sub>3</sub>Sn Rough?

- Nb<sub>3</sub>Sn roughness comes from growth
  - **Bad** Sn nucleation -> **rough surface**
  - **Good** Sn nucleation -> **smooth surface**



## Nb<sub>3</sub>Sn Growth:

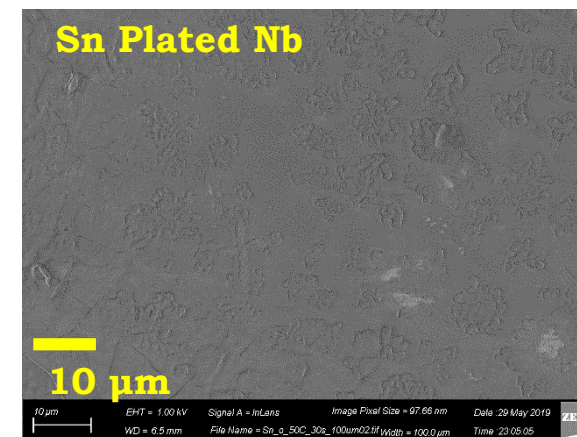
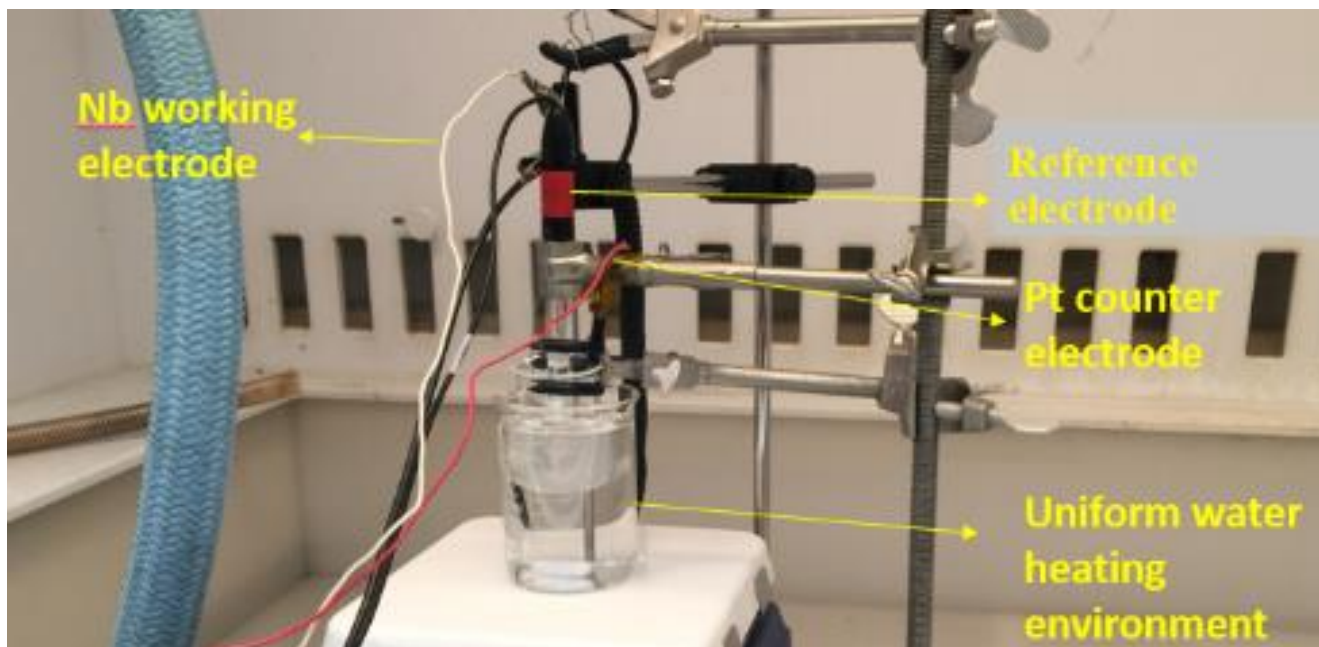




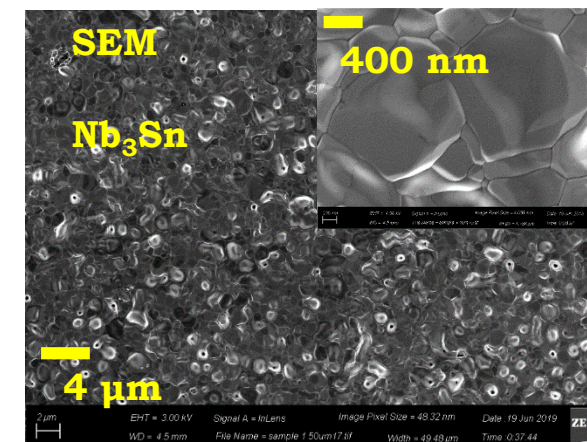
# Sn Electroplating

Zeming Sun (Cornell):

- Electroplate Sn onto Nb before heat treatment
  - > Grow smoother  $\text{Nb}_3\text{Sn}$



Heat Treatment





# Sn Electroplating

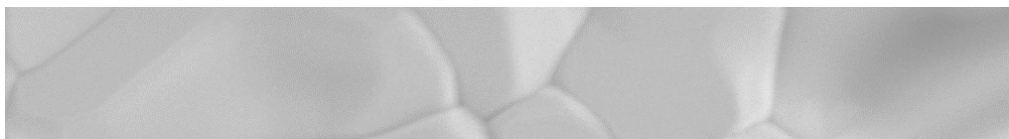
Sn<sub>2</sub>Cl Nucleation

R<sub>a</sub> ~ 300 nm



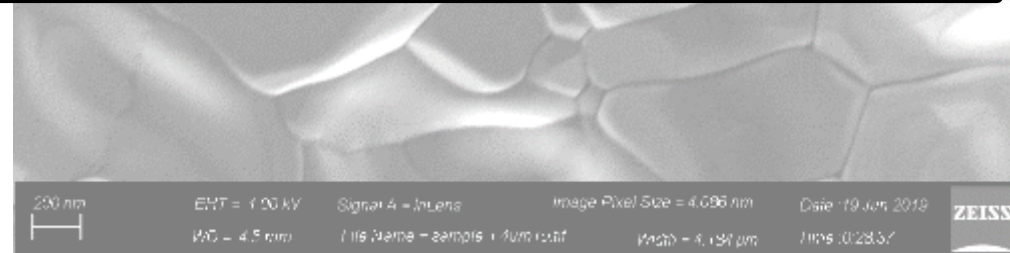
“Sn Plating Nucleation”

R<sub>a</sub> ~ 70 nm



Conclusion:

Sn plating nucleation 5 x roughness reduction!



Next step: Grow entire cavity using Sn plating

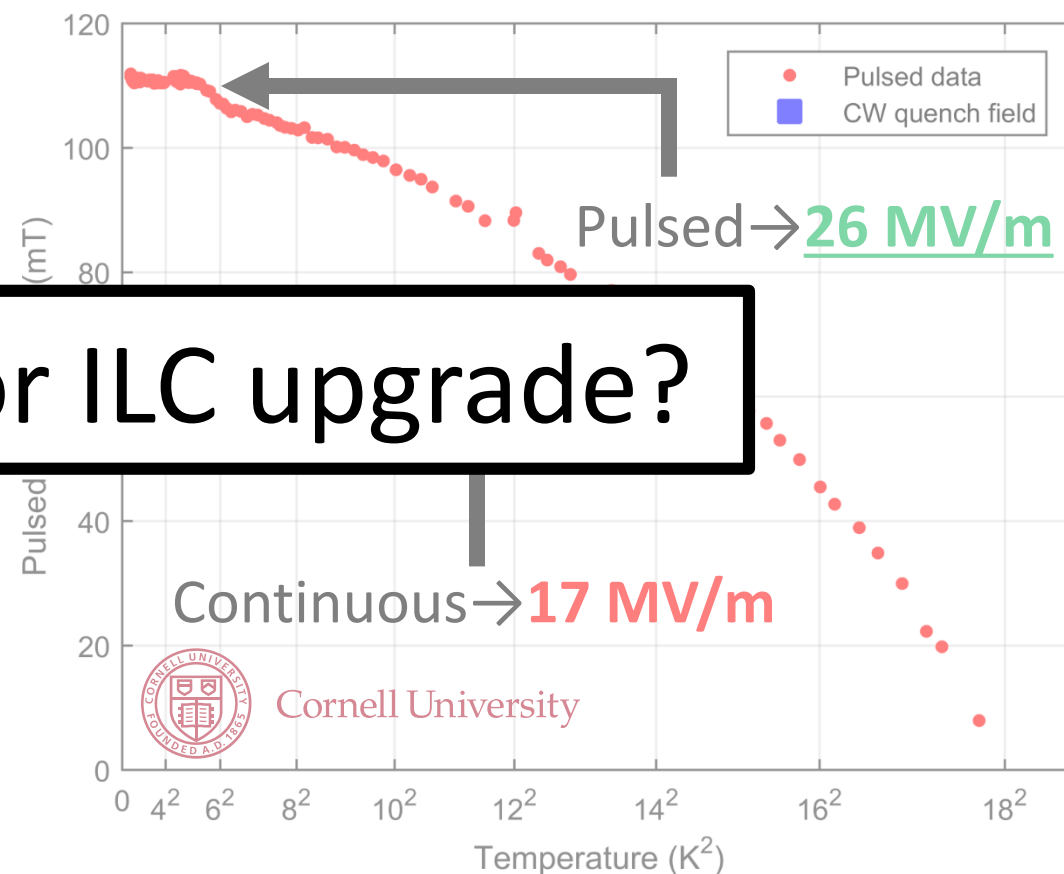
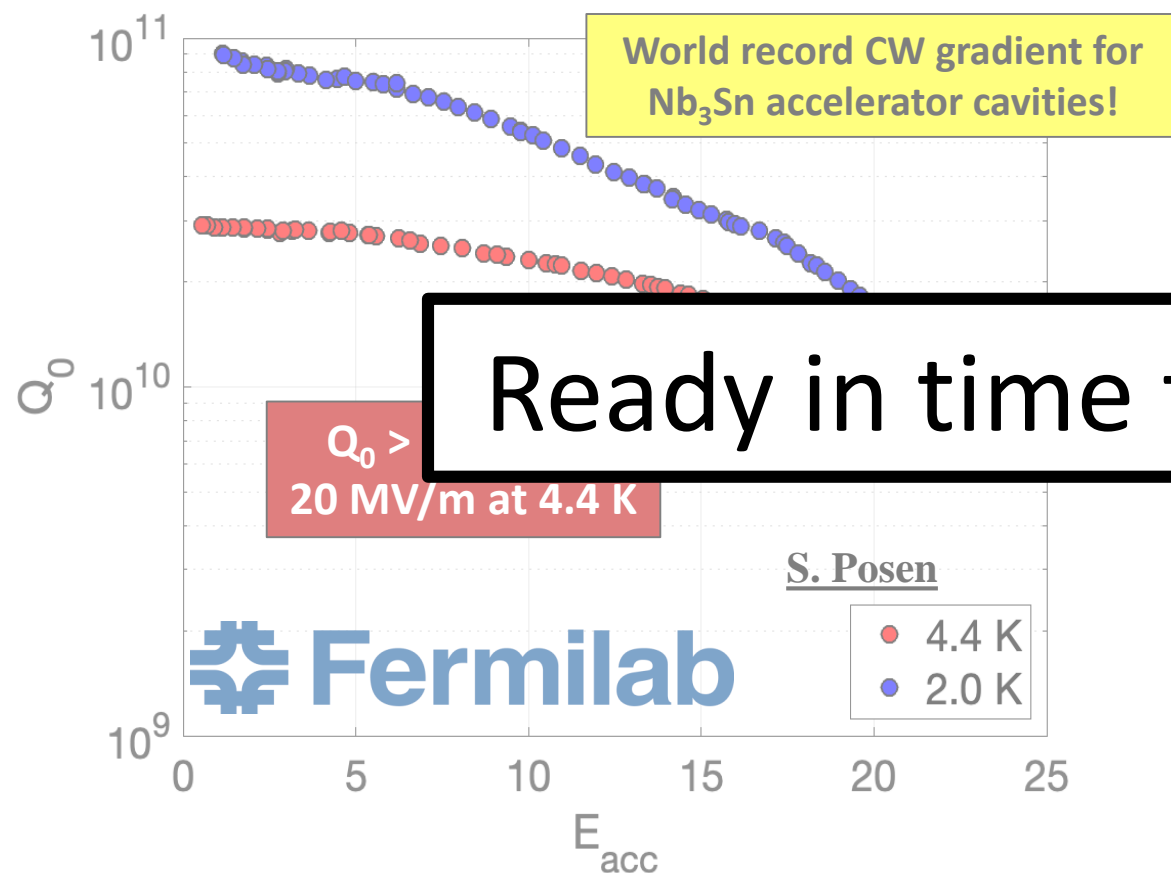


# Outlook



# Nb<sub>3</sub>Sn Outlook: Making Great Progress!

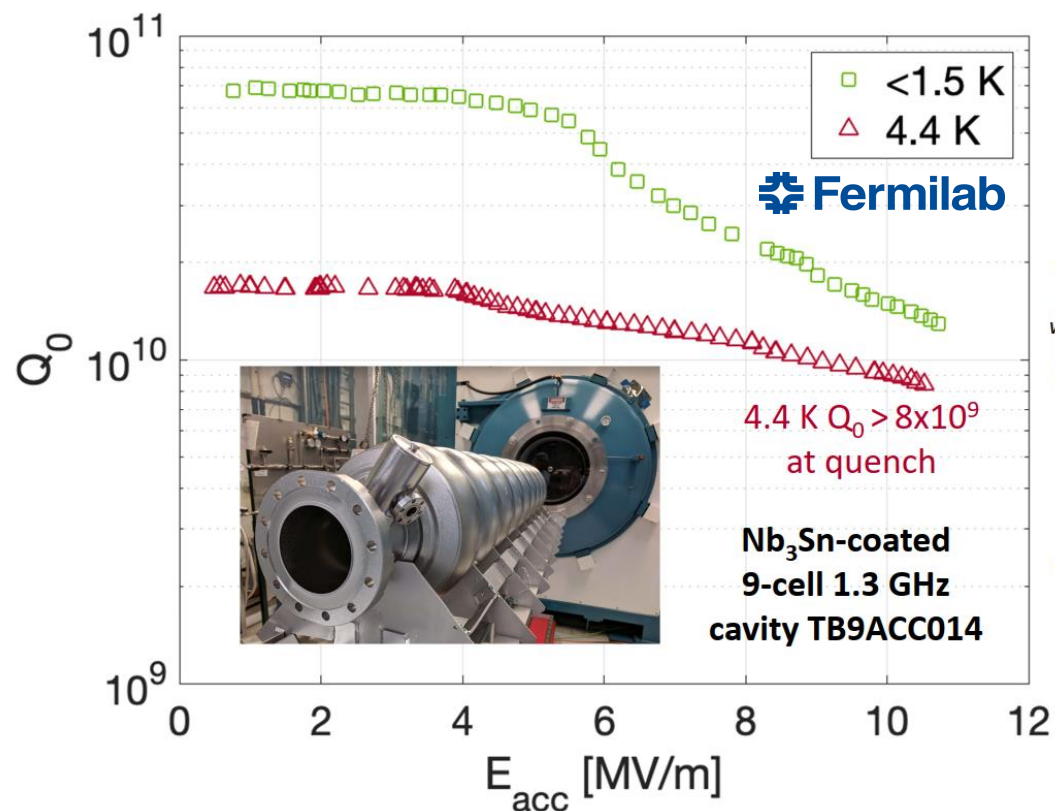
- Sam Posen (FNAL) reached 22 MV/m in CW operation (Nb<sub>3</sub>Sn world record)!
- Pulsed operation can reach 25 MV/m
  - Does not (yet) reach ILC spec. but reaches old TESLA spec.



Ref: S. Posen, "Frequency Dependence Studies of Nb<sub>3</sub>Sn Cavities," presented at TTC 2019, Vancouver, Canada, Feb. 2019

# 9-Cell Cavity Work at Fermilab

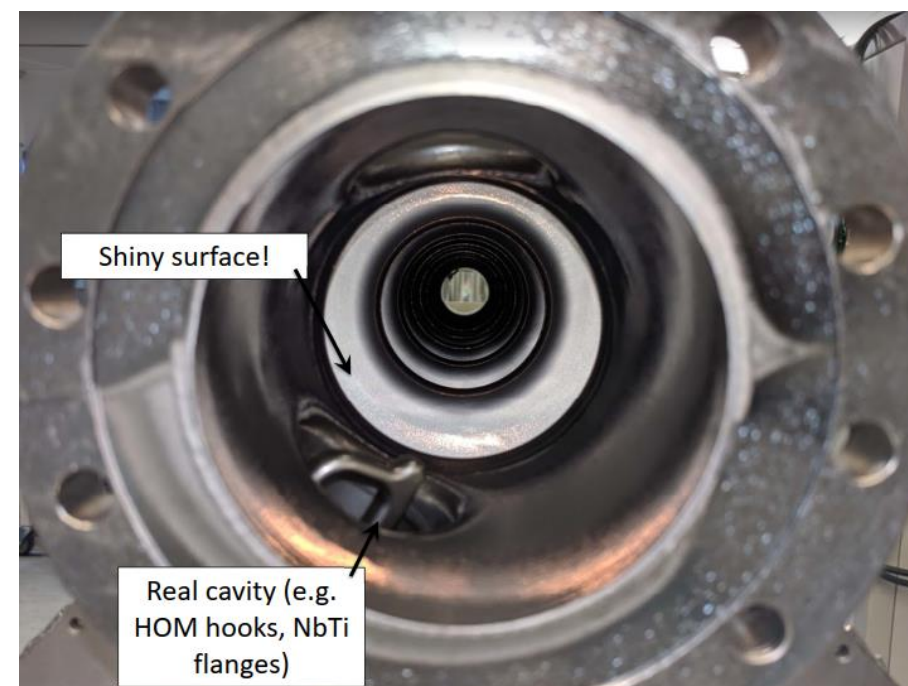
- Sam Posen (Fermilab) completed a first coating of a **9-cell cavity**
  - Real cavity that could be put in cryomodule
- $E_{acc} \sim 10.5 \text{ MV/m}$ ,  $Q \sim 8 \times 10^9$  at 4.4 K!
- First attempt: expect even better results soon!



*Cavity was not field flatness tuned nor was flatness checked prior to test. Cavity will be tested again after these steps.*

*Includes correction for stainless steel flanges  $2 \times 0.8 \text{ n}\Omega$*

## Fermilab



Ref: S. Posen et. al., "Nb<sub>3</sub>Sn at Fermilab: Exploring Performance," in Proc. of SRF2019, Hamburg, Germany, July 2019



# Conclusions

- **3 x more efficient** than clean Nb
  - Can further **double efficiency**
  - **Lower dynamic load**
- **4.2 K** operation
  - **Lower static load**
  - **Simpler cryogenics system**
- 2.6 GHz cavity just as efficient
  - **Smaller cavities -> Lower Cost**
- Can reach **23 MV/m** CW (FNAL)
- Can reach **25 MV/m** pulsed (Cornell)
- Reducing surface roughness is a critical next step to improve quench fields
  - **Can grow smoother Nb<sub>3</sub>Sn** with Sn plating
  - Only need 25% increase in  $E_{acc}$  for ILC operating spec



# Acknowledgements

The Cornell Nb<sub>3</sub>Sn program is supported by:  
U.S. DOE award DE-SC0008431: 1.3 GHz Nb<sub>3</sub>Sn tests and Nb<sub>3</sub>Sn R&D  
NSF Award 1734189: 2.6 GHz and 3.9 GHz tests and R&D  
Center for Bright Beam (NSF Award 1549132): Materials studies

This work makes use of Cornell Center for Materials Research, NSF MRSEC program (DMR-1719875)  
**with special thanks to**

Prof. Matthias Liepe	Dr. Danilo Liarte	Nathan Sitaraman	John Kaufman
Prof. Tomas Arias	Dr. Zeming Sun	James Maniscalco	Holly Conklin
Prof. David A. Muller	Dr. Daniel Hall	Alden Pack	Terri Gruber
Prof. James P. Sethna	Dr. Sam Posen	James Sears	Paul Bishop
Prof. Mark Transtrum	Paul Cueva	Greg Kulina	Adam Holic

